

## LMV82x Single/Dual/Quad, Low Voltage, Low Power, RRO, 5 MHz Operational Amplifiers

### 1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified With the Following Results:
  - LMV822-Q1 And LMV824-Q1 Are Available in Automotive AEC-Q100 Grade 1 Version
- For  $V_s = 5\text{ V}$ , Typical Supply Values Unless Otherwise Noted
- LMV824 Available With Extended Temperature Range to  $125^\circ\text{C}$
- Small SC70-5 Package  $2.0 \times 1.25 \times 0.95\text{ mm}$
- Specified Performance At  $2.5\text{ V}$ ,  $2.7\text{ V}$  and  $5\text{ V}$
- $V_{OS}$   $3.5\text{ mV}$  (Max)
- $TCV_{OS}$   $1\text{ }\mu\text{V}/^\circ\text{C}$
- Gain Bandwidth Product At  $2.7\text{ V}$ ,  $5\text{ MHz}$
- $I_{Supply}$  At  $2.7\text{ V}$  Supply,  $220\text{ }\mu\text{A}$  per Amplifier
- Slew Rate  $1.4\text{ V}/\mu\text{s}$  (Min)
- CMRR  $90\text{ dB}$
- PSRR  $85\text{ dB}$
- $V_{CM}$  At  $5\text{ V}$  Supply,  $-0.3\text{ V}$  to  $4.3\text{ V}$
- Rail to Rail Output (RRO)
  - $600\text{ }\Omega$  Load,  $160\text{ mV}$  From Rail
  - $10\text{ k}\Omega$  Load,  $55\text{ mV}$  From Rail
- Stable Performance with Capacitive Loads

### 2 Applications

- Cordless Phones
- Cellular Phones
- Laptops
- PDAs
- PCMCIA

### 3 Description

The LMV821/LMV822/LMV824 op amps bring performance and economy to low voltage, low power systems. With a  $5\text{ MHz}$  unity-gain frequency, at  $2.7\text{ V}$  supply, and a  $1.4\text{ V}/\mu\text{s}$  slew rate, the quiescent current is only  $220\text{ }\mu\text{A}$  per amplifier. They provide rail to rail output (RRO) swing into  $600\text{ }\Omega$  load. The input common-mode voltage range includes ground and the maximum input offset voltage is  $3.5\text{ mV}$ . They are also capable of easily driving large capacitive loads as indicated in the applications section.

The LMV821 single op amp is available in the tiny SC70-5 package, which is about half the size of the previous title holder, the SOT23-5. The LMV824NDGV is specified over the extended industrial temperature range and is in a TVSOP package.

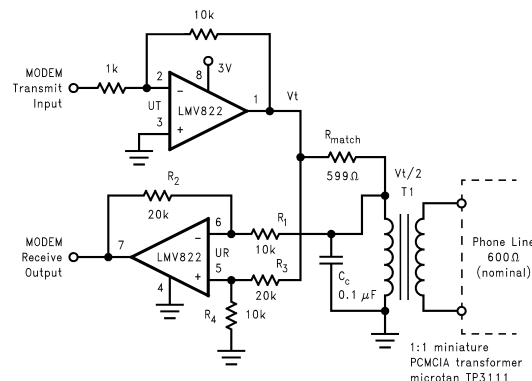
Overall, the LMV821/LMV822/LMV824 devices are low voltage, low power and performance op amps designed for a wide range of applications at an economical price.

#### Device Information<sup>(1)</sup>

| DEVICE NAME | PACKAGE    | BODY SIZE                              |
|-------------|------------|--|
| LMV821-N    | SOT23 (5)  | $2.92\text{ mm} \times 1.60\text{ mm}$ |
|             | SC70 (5)   | $2.00\text{ mm} \times 1.25\text{ mm}$ |
| LMV822-N    | SOIC (8)   | $4.90\text{ mm} \times 3.91\text{ mm}$ |
|             | VSSOP (8)  | $3.00\text{ mm} \times 3.00\text{ mm}$ |
| LMV822-N-Q1 | VSSOP (8)  | $3.00\text{ mm} \times 3.00\text{ mm}$ |
| LMV824-N    | SOIC (14)  | $8.65\text{ mm} \times 3.91\text{ mm}$ |
|             | TSSOP (14) | $5.00\text{ mm} \times 4.40\text{ mm}$ |
| LMV824-N-Q1 | TSSOP (14) | $5.00\text{ mm} \times 4.40\text{ mm}$ |
| LMV824I     | TVSOP (14) | $4.40\text{ mm} \times 3.60\text{ mm}$ |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### Telephone Line Transceiver for PCMCIA Modem Card

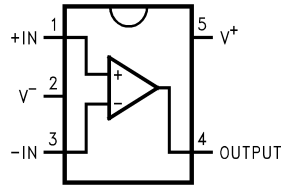




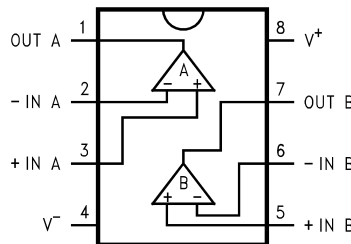


## 5 Pin Configuration and Functions

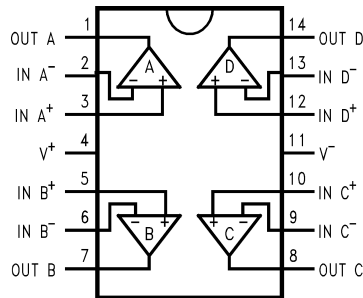
**5-Pin SC70-5/SOT23-5**  
**DCK0005A, DBV0005A Packages**  
**Top View**



**8-Pin SOIC/VSSOP**  
**D0008A, DGK0008A Packages**  
**Top View**



**14-Pin SOIC/TSSOP/TVSOP**  
**D0014A, PW0014A, DGV0014A Packages**  
**Top View**



### Pin Functions

| PIN NAME | I/O | DESCRIPTION         |
|----------|-----|---------------------|
| +IN      | I   | Non-Inverting Input |
| -IN      | I   | Inverting Input     |
| OUT      | O   | Output              |
| V-       | P   | Negative Supply     |
| V+       | P   | Positive Supply     |

## 6 Specifications

### 6.1 Absolute Maximum Ratings<sup>(1)(2)</sup>

|   | MIN            | MAX                | UNIT |
|---|----------------|--------------------|------|
| Differential Input Voltage                            | V <sup>-</sup> | V <sup>+</sup>     | V    |
| Supply Voltage (V <sup>+</sup> – V <sup>-</sup> )     | -0.3           | 5.5                | V    |
| Output Short Circuit to V <sup>+</sup> <sup>(3)</sup> |                | See <sup>(3)</sup> |      |
| Output Short Circuit to V <sup>-</sup> <sup>(3)</sup> |                | See <sup>(3)</sup> |      |
| Soldering Information                                 |                |                    |      |
| Infrared or Convection (20 sec)                       |                | 235                | °C   |
| Junction Temperature <sup>(4)</sup>                   |                | 150                | °C   |
| Storage Temperature T <sub>stg</sub>                  | -65            | 150                | °C   |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
- (3) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability.
- (4) The maximum power dissipation is a function of T<sub>J(max)</sub>, θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any ambient temperature is P<sub>D</sub> = (T<sub>J(max)</sub>–T<sub>A</sub>)/θ<sub>JA</sub>. All numbers apply for packages soldered directly into a PC board.

### 6.2 ESD Ratings

|                    |                         |  | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup><br><sup>(2)(3)</sup> | ±2000 | V    |
|                    |                         | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup><br>LMV821            | ±1500 |      |
|                    |                         | Machine Model (MM) <sup>(4)</sup>  | ±200  |      |

- (1) Level listed above is the passing level per ANSI, ESDA, and JEDEC JS-001. JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) Human body model, 1.5 kΩ in series with 100 pF.
- (3) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification for Q grade devices.
- (4) Machine model, 200Ω in series with 100 pF.

### 6.3 Recommended Operating Conditions

|                   |                                  | MIN | NOM | MAX | UNIT |
|-------------------|----------------------------------|-----|-----|-----|------|
| Supply Voltage    |                                  | 2.5 |     | 5.5 | V    |
| Temperature Range | LMV821, LMV822, LMV824           | -40 |     | 85  | °C   |
|                   | LMV822-Q1, LMV824I and LMV824-Q1 | -40 |     | 125 |      |

### 6.4 Thermal Information, 5 Pins<sup>(1)</sup>

| THERMAL METRIC <sup>(1)</sup> |  | DCK<br>SC70-5<br>PACKAGE | DBV<br>SOT23-5<br>PACKAGE | UNIT |
|-------------------------------|--|--------------------------|---------------------------|------|
|                               |  | 5 PIN                    | 5 PIN                     |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 263.4                    | 217.8                     | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 102.8                    | 142.4                     | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 50.9                     | 49.4                      | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 3.7                      | 29.1                      | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 50.2                     | 48.5                      | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | N/A                      | N/A                       | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Thermal Information, 8 Pins<sup>(1)</sup>

| THERMAL METRIC <sup>(1)</sup> |  | D SOIC PACKAGE | DGK VSSOP PACKAGE | UNIT |
|-------------------------------|--|----------------|-------------------|------|
|                               |  | 8 PIN          | 8 PIN             |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 132.6          | 193.9             | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 76.9           | 84.4              | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 73.2           | 114.5             | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 25.0           | 21.6              | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 72.6           | 113.0             | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | N/A            | N/A               | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.6 Thermal Information, 14 Pins<sup>(1)</sup>

| THERMAL METRIC <sup>(1)</sup> |  | D SOIC PACKAGE | PW TSSOP PACKAGE | DGV TVSOP PACKAGE | UNIT |
|-------------------------------|--|----------------|------------------|-------------------|------|
|                               |  | 14 PIN         | 14 PIN           | 14 PIN            |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 109.7          | 135.6            | 148.2             | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 65.9           | 63.8             | 67.3              | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 64.1           | 77.4             | 77.5              | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 24.5           | 13.0             | 12.9              | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 63.9           | 76.8             | 76.9              | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | N/A            | N/A              | N/A               | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.7 DC Electrical Characteristics 2.7V

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = 1.0\text{V}$ ,  $V_O = 1.35\text{V}$  and  $R_L > 1\text{M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER  | TEST CONDITIONS                         | MIN <sup>(1)</sup>  | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT                         |
|------------|---|---|--------------------|--------------------|------------------------------|
| $V_{OS}$   | LMV821/822/822-Q1/824                   |   | 1                  | 3.5                | mV                           |
|            | LMV821/822/822-Q1/824, Over Temperature |   |                    | 4                  |                              |
|            | LMV824-Q1/LMV824I                       |   | 1                  |                    |                              |
|            | LMV824-Q1/LMV824I, Over Temperature     |   |                    | 5.5                |                              |
| $TCV_{OS}$ | Input Offset Voltage Average Drift      |   | 1                  |                    | $\mu\text{V}/^\circ\text{C}$ |
| $I_B$      | Input Bias Current                      |   | 30                 | 90                 | nA                           |
|            | Over Temperature                        |   |                    | 140                |                              |
| $I_{OS}$   | Input Offset Current                    |   | 0.5                | 30                 | nA                           |
|            | Over Temperature                        |   |                    | 50                 |                              |
| CMRR       | Common Mode Rejection Ratio             | $0\text{V} \leq V_{CM} \leq 1.7\text{V}$  | 70                 | 85                 | dB                           |
|            |   | $0\text{V} \leq V_{CM} \leq 1.7\text{V}$ , Over Temperature   | 68                 |                    |                              |
| +PSRR      | Positive Power Supply Rejection Ratio   | $1.7\text{V} \leq V^+ \leq 4\text{V}$ , $V^- = 1\text{V}$ , $V_O = 0\text{V}$ , $V_{CM} = 0\text{V}$<br>LMV821/822/824/824-Q1/LMV824I                   | 75                 | 85                 | dB                           |
|            |   | $1.7\text{V} \leq V^+ \leq 4\text{V}$ , $V^- = 1\text{V}$ , $V_O = 0\text{V}$ , $V_{CM} = 0\text{V}$<br>LMV821/822/824/824-Q1/LMV824I, Over Temperature | 70                 |                    |                              |
|            |   | LMV822-Q1   | 75                 | 85                 |                              |

(1) All limits are ensured by testing or statistical analysis.

(2) Typical Values represent the most likely parametric norm.

## DC Electrical Characteristics 2.7V (continued)

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = 1.0\text{V}$ ,  $V_O = 1.35\text{V}$  and  $R_L > 1\text{M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER   | TEST CONDITIONS  | MIN <sup>(1)</sup>  | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT |
|---|--|---|--------------------|--------------------|------|
| -PSRR<br>Negative Power<br>Supply Rejection<br>Ratio                        | $-1.0\text{V} \leq V^- \leq -3.3\text{V}$ , $V^+ = 1.7\text{V}$ , $V_O = 0\text{V}$ , $V_{\text{CM}} = 0\text{V}$<br>LMV821/822/824/824-Q1/LMV824I                   | 73  | 85                 |                    | dB   |
|   | $-1.0\text{V} \leq V^- \leq -3.3\text{V}$ , $V^+ = 1.7\text{V}$ , $V_O = 0\text{V}$ , $V_{\text{CM}} = 0\text{V}$<br>LMV821/822/824/824-Q1/LMV824I, Over Temperature | 70  |                    |                    |      |
|   | LMV822-Q1  | 73  | 85                 |                    |      |
| $V_{\text{CM}}$<br>Input Common-Mode<br>Voltage Range                       | For CMRR $\geq 50\text{dB}$  |   | -0.3               | -0.2               | V    |
|   |  | 1.9   | 2.0                |                    |      |
| $A_v$<br>Large Signal Voltage<br>Gain                                       | Sourcing, $R_L = 600\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $2.2\text{V}$ ;<br>LMV821/822/824   | 90  | 100                |                    | dB   |
|   | Sourcing, $R_L = 600\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $2.2\text{V}$ ;<br>LMV821/822/824, Over Temperature                                       | 85  |                    |                    |      |
|   | LMV822-Q1/LMV824-Q1/LMV824I  | 90  | 100                |                    |      |
|   | Sinking, $R_L = 600\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $0.5\text{V}$<br>LMV821/822/824  | 85  | 90                 |                    | dB   |
|   | Sinking, $R_L = 600\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $0.5\text{V}$<br>LMV821/822/824, Over Temperature  | 80  |                    |                    |      |
|   | LMV824I  | 85  | 90                 |                    |      |
|   | LMV824I, Over Temperature  | 78  |                    |                    |      |
|   | LMV822-Q1/LMV824-Q1  | 85  | 90                 |                    |      |
|   | Sourcing, $R_L = 2\text{k}\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $2.2\text{V}$ ;<br>LMV821/822/824   | 95  | 100                |                    |      |
|   | Sourcing, $R_L = 2\text{k}\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $2.2\text{V}$ ;<br>LMV821/822/824, Over Temperature                                 | 90  |                    |                    |      |
|   | LMV822-Q1/LMV824-Q1/LMV824I  | 95  | 100                |                    |      |
|   | Sinking, $R_L = 2\text{k}\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $0.5\text{V}$<br>LMV821/822/824  | 90  | 95                 |                    | dB   |
|   | Sinking, $R_L = 2\text{k}\Omega$ to $1.35\text{V}$ ,<br>$V_O = 1.35\text{V}$ to $0.5\text{V}$<br>LMV821/822/824, Over Temperature                                    | 85  |                    |                    |      |
|   | LMV822-Q1/LMV824-Q1/LMV824I  | 90  | 95                 |                    |      |
|   | $V_O$<br>Output Swing  | $V^+ = 2.7\text{V}$ , $R_L = 600\Omega$ to $1.35\text{V}$ | 2.50               | 2.58               |      |
|   |  |   | 0.13               | 0.20               |      |
| $V^+ = 2.7\text{V}$ , $R_L = 600\Omega$ to $1.35\text{V}$ , Over Temp       |  | 2.40  |                    | 0.30               | V    |
| $V^+ = 2.7\text{V}$ , $R_L = 2\text{k}\Omega$ to $1.35\text{V}$             |  | 2.60  | 2.66               |                    |      |
|   |  |   | 0.08               | 0.120              |      |
| $V^+ = 2.7\text{V}$ , $R_L = 2\text{k}\Omega$ to $1.35\text{V}$ , Over Temp | 2.50   |   | 0.200              |                    |      |
| $I_O$<br>Output Current   | Sourcing, $V_O = 0\text{V}$  | 12  | 16                 |                    | mA   |
|   | Sinking, $V_O = 2.7\text{V}$   | 12  | 26                 |                    |      |

**DC Electrical Characteristics 2.7V (continued)**

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = 1.0\text{V}$ ,  $V_O = 1.35\text{V}$  and  $R_L > 1\text{M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER               | TEST CONDITIONS          | MIN <sup>(1)</sup> | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT |
|-------------------------|--------------------------|--------------------|--------------------|--------------------|------|
| $I_S$<br>Supply Current | LMV821 (Single)          |                    | 0.22               | 0.3                | mA   |
|                         | LMV821, Over Temperature |                    |                    | 0.5                |      |
|                         | LMV822 (Dual)            |                    | 0.45               | 0.6                | mA   |
|                         | LMV822, Over Temperature |                    |                    | 0.8                |      |
|                         | LMV824 (Quad)            |                    | 0.72               | 1.0                | mA   |
|                         | LMV824, Over Temperature |                    |                    | 1.2                |      |



## 6.8 DC Electrical Characteristics 2.5V

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = 1.0\text{V}$ ,  $V_O = 1.25\text{V}$  and  $R_L > 1\text{M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER       |                      | CONDITION  | MIN <sup>(1)</sup> | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT |
|-----------------|----------------------|--|--------------------|--------------------|--------------------|------|
| $V_{\text{OS}}$ | Input Offset Voltage | LMV821/822/822-Q1/824  |                    | 1                  | 3.5                | mV   |
|                 |                      | LMV821/822/822-Q1/824, Over Temperature  |                    |                    | 4                  |      |
|                 |                      | LMV824-Q1/LMV824I  |                    | 1                  |                    |      |
|                 |                      | LMV824-Q1/LMV824I, Over Temperature  |                    |                    | 5.5                |      |
| $V_O$           | Output Swing         | $V^+ = 2.5\text{V}$ , $R_L = 600\Omega$ to $1.25\text{V}$                          | 2.30               | 2.37               |                    | V    |
|                 |                      | $V^+ = 2.5\text{V}$ , $R_L = 600\Omega$ to $1.25\text{V}$ , Over Temperature       |                    | 0.13               | 0.20               |      |
|                 |                      | $V^+ = 2.5\text{V}$ , $R_L = 2\text{k}\Omega$ to $1.25\text{V}$                    | 2.20               | 2.46               | 0.30               | V    |
|                 |                      | $V^+ = 2.5\text{V}$ , $R_L = 2\text{k}\Omega$ to $1.25\text{V}$ , Over Temperature | 2.40               | 0.08               | 0.12               |      |
|                 |                      | 2.30   |                    | 0.20               |                    |      |

(1) All limits are ensured by testing or statistical analysis.

(2) Typical Values represent the most likely parametric norm.

## 6.9 AC Electrical Characteristics 2.7V

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = 1.0\text{V}$ ,  $V_O = 1.35\text{V}$  and  $R_L > 1\text{M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER |                              | TEST CONDITIONS  | MIN <sup>(1)</sup> | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT                   |
|-----------|------------------------------|--|--------------------|--------------------|--------------------|------------------------|
| SR        | Slew Rate                    | See <sup>(3)</sup>   |                    | 1.5                |                    | V/ $\mu\text{s}$       |
| GBW       | Gain-Bandwidth Product       |  |                    | 5                  |                    | MHz                    |
| $\Phi_m$  | Phase Margin                 |  |                    | 61                 |                    | Deg.                   |
| $G_m$     | Gain Margin                  |  |                    | 10                 |                    | dB                     |
|           | Amp-to-Amp Isolation         | See <sup>(4)</sup>   |                    | 135                |                    | dB                     |
| $e_n$     | Input-Related Voltage Noise  | $f = 1\text{ kHz}$ , $V_{\text{CM}} = 1\text{V}$   |                    | 28                 |                    | nV/ $\sqrt{\text{Hz}}$ |
| $i_n$     | Input-Referred Current Noise | $f = 1\text{ kHz}$   |                    | 0.1                |                    | pA/ $\sqrt{\text{Hz}}$ |
| THD       | Total Harmonic Distortion    | $f = 1\text{ kHz}$ , $A_V = -2$ , $R_L = 10\text{ k}\Omega$ , $V_O = 4.1\text{ V}_{\text{PP}}$ |                    | 0.01%              |                    |                        |

(1) All limits are ensured by testing or statistical analysis.

(2) Typical Values represent the most likely parametric norm.

(3)  $V^+ = 5\text{V}$ . Connected as voltage follower with 3V step input. Number specified is the slower of the positive and negative slew rates.

(4) Input referred,  $V^+ = 5\text{V}$  and  $R_L = 100\text{k}\Omega$  connected to  $2.5\text{V}$ . Each amp excited in turn with 1 kHz to produce  $V_O = 3\text{ V}_{\text{PP}}$ .

## 6.10 DC Electrical Characteristics 5V

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = 2.0\text{V}$ ,  $V_O = 2.5\text{V}$  and  $R_L > 1\text{M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER                |                                    | TEST CONDITIONS                         | MIN <sup>(1)</sup> | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT                         |
|--------------------------|------------------------------------|---|--------------------|--------------------|--------------------|------------------------------|
| $V_{\text{OS}}$          | Input Offset Voltage               | LMV821/822/822-Q1/824                   |                    | 1                  | 3.5                | mV                           |
|                          |                                    | LMV821/822/822-Q1/824, Over Temperature |                    |                    | 4.0                |                              |
|                          |                                    | LMV824-Q1/LMV824I                       |                    | 1                  |                    |                              |
|                          |                                    | LMV824-Q1/ LMV824I, Over Temperature    |                    |                    | 5.5                |                              |
| $\text{TCV}_{\text{OS}}$ | Input Offset Voltage Average Drift |   |                    | 1                  |                    | $\mu\text{V}/^\circ\text{C}$ |

(1) All limits are ensured by testing or statistical analysis.

(2) Typical Values represent the most likely parametric norm.

## DC Electrical Characteristics 5V (continued)

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = 2.0\text{V}$ ,  $V_O = 2.5\text{V}$  and  $R_L > 1\text{M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER       |                                       | TEST CONDITIONS   | MIN <sup>(1)</sup> | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT |
|-----------------|---------------------------------------|---|--------------------|--------------------|--------------------|------|
| $I_B$           | Input Bias Current                    |   |                    | 40                 | 100                | nA   |
|                 |                                       | Over Temperature  |                    |                    | 150                |      |
| $I_{\text{OS}}$ | Input Offset Current                  |   |                    | 0.5                | 30                 | nA   |
|                 |                                       | Over Temperature  |                    |                    | 50                 |      |
| CMRR            | Common Mode Rejection Ratio           | $0\text{V} \leq V_{\text{CM}} \leq 4.0\text{V}$   | 72                 | 90                 |                    | dB   |
|                 |                                       | $0\text{V} \leq V_{\text{CM}} \leq 4.0\text{V}$ , Over Temperature  | 70                 |                    |                    |      |
| +PSRR           | Positive Power Supply Rejection Ratio | $1.7\text{V} \leq V^+ \leq 4\text{V}$ , $V^- = 1\text{V}$ , $V_O = 0\text{V}$ , $V_{\text{CM}} = 0\text{V}$<br>LMV821/822/824/824-Q1/824I                   |                    | 85                 | 75                 | dB   |
|                 |                                       | $1.7\text{V} \leq V^+ \leq 4\text{V}$ , $V^- = 1\text{V}$ , $V_O = 0\text{V}$ , $V_{\text{CM}} = 0\text{V}$<br>LMV821/822/824/824-Q1/824I, Over Temperature |                    |                    | 70                 |      |
|                 |                                       | LMV822-Q1   | 75                 | 85                 |                    |      |
| -PSRR           | Negative Power Supply Rejection Ratio | $-1.0\text{V} \leq V^- \leq -3.3\text{V}$ , $V^+ = 1.7\text{V}$ , $V_O = 0\text{V}$ , $V_{\text{CM}} = 0\text{V}$<br>LMV821/822/824/824-Q1/824I             | 73                 | 85                 |                    | dB   |
|                 |                                       | $-1.0\text{V} \leq V^- \leq -3.3\text{V}$ , $V^+ = 1.7\text{V}$ , $V_O = 0\text{V}$ , $V_{\text{CM}} = 0\text{V}$<br>LMV821/822/824/824-Q1/824I             | 70                 |                    |                    |      |
|                 |                                       | LMV822-Q1   | 73                 | 85                 |                    |      |
| $V_{\text{CM}}$ | Input Common-Mode Voltage Range       | For CMRR $\geq 50\text{dB}$   |                    | -0.3               | -0.2               | V    |
|                 |                                       |   | 4.2                | 4.3                |                    | V    |
| $A_V$           | Large Signal Voltage Gain             | Sourcing, $R_L = 600\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $4.5\text{V}$ ;<br>LMV821/822/824  | 95                 | 105                |                    | dB   |
|                 |                                       | Sourcing, $R_L = 600\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $4.5\text{V}$ ;<br>LMV821/822/824, Over Temperature                                | 90                 |                    |                    |      |
|                 |                                       | LMV822-Q1/LMV824-Q1/LMV824I   | 95                 | 105                |                    |      |
|                 |                                       | Sinking, $R_L = 600\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $0.5\text{V}$<br>LMV821/822/824   | 95                 | 105                |                    | dB   |
|                 |                                       | Sinking, $R_L = 600\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $0.5\text{V}$<br>LMV821/822/824, Over Temperature                                   | 90                 |                    |                    |      |
|                 |                                       | LMV824I   | 95                 | 105                |                    |      |
|                 |                                       | LMV824I, Over Temperature   | 82                 |                    |                    |      |
|                 |                                       | LMV822-Q1/LMV824-Q1   | 95                 | 105                |                    |      |
|                 |                                       | Sourcing, $R_L = 2\text{k}\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $4.5\text{V}$ ;<br>LMV821/822/824  | 95                 | 105                |                    |      |
|                 |                                       | Sourcing, $R_L = 2\text{k}\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $4.5\text{V}$ ;<br>LMV821/822/824, Over Temperature                          | 90                 |                    |                    |      |
|                 |                                       | LMV822-Q1/LMV824-Q1/LMV824I   | 95                 | 105                |                    |      |
|                 |                                       | Sinking, $R_L = 2\text{k}\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $0.5\text{V}$<br>LMV821/822/824   | 95                 | 105                |                    | dB   |
|                 |                                       | Sinking, $R_L = 2\text{k}\Omega$ to $2.5\text{V}$ ,<br>$V_O = 2.5\text{V}$ to $0.5\text{V}$<br>LMV821/822/824, Over Temperature                             | 90                 |                    |                    |      |
|                 |                                       | LMV822-Q1/LMV824-Q1/LMV824I   | 95                 | 105                |                    |      |

**DC Electrical Characteristics 5V (continued)**

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 5\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{\text{CM}} = 2.0\text{ V}$ ,  $V_O = 2.5\text{ V}$  and  $R_L > 1\text{ M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER | TEST CONDITIONS  | MIN <sup>(1)</sup>   | TYP <sup>(2)</sup>                                 | MAX <sup>(1)</sup> | UNIT  |      |   |
|-----------|--|--|--|--------------------|-------|------|---|
| $V_O$     | Output Swing   | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V  | 4.75   | 4.84               |       | V    |   |
|           |  | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V, Over Temperature                      | 4.70   |                    |       |      |   |
|           |  | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V (LMV824-Q1, LMV824I)                   |  | 4.84               |       |      |   |
|           |  | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V (LMV824-Q1, LMV824I), Over Temperature | 4.60   |                    |       |      |   |
|           |  | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V  |  | 0.17               | 0.250 | V    |   |
|           |  | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V, Over Temperature                      |  |                    | 0.30  |      |   |
|           |  | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V (LMV824-Q1, LMV824I)                   |  | 0.17               |       |      |   |
|           |  | $V^+ = 5\text{ V}, R_L = 600\Omega$ to 2.5V (LMV824-Q1, LMV824I), Over Temperature |  |                    | 0.40  |      |   |
|           |  |  | $V^+ = 5\text{ V}, R_L = 2\text{ k}\Omega$ to 2.5V | 4.85               | 4.90  |      | V |
|           |  |  |  |                    | 0.10  | 0.15 |   |
|           | $V^+ = 5\text{ V}, R_L = 2\text{ k}\Omega$ to 2.5V, Over Temperature | 4.80   |  | 0.20               |       |      |   |
|           |  |  |  |                    |       |      |   |
| $I_O$     | Output Current   | Sourcing, $V_O = 0\text{ V}$   | 20   | 45                 |       | mA   |   |
|           |  | Sourcing, $V_O = 0\text{ V}$ , Over Temperature                                    | 15   |                    |       |      |   |
|           |  | Sourcing, $V_O = 0\text{ V}$<br>LMV824I  | 20   | 45                 |       | mA   |   |
|           |  | Sourcing, $V_O = 0\text{ V}$<br>LMV824I, Over Temperature                          | 10   |                    |       |      |   |
|           |  | Sinking, $V_O = 5\text{ V}$  | 20   | 40                 |       | mA   |   |
|           |  | Sinking, $V_O = 5\text{ V}$ , Over Temperature                                     | 15   |                    |       |      |   |
|           |  | Sinking, $V_O = 5\text{ V}$<br>LMV824I   | 20   | 40                 |       | mA   |   |
|           |  | Sinking, $V_O = 5\text{ V}$<br>LMV824I, Over Temperature                           | 10   |                    |       |      |   |
| $I_S$     | Supply Current   | LMV821 (Single)  |  | 0.30               | 0.4   | mA   |   |
|           |  | LMV821, Over Temperature   |  |                    | 0.6   |      |   |
|           |  | LMV822 (Dual)  |  | 0.5                | 0.7   | mA   |   |
|           |  | LMV822, Over Temperature   |  |                    | 0.9   |      |   |
|           |  | LMV824 (Quad)  |  | 1.0                | 1.3   | mA   |   |
|           |  | LMV824, Over Temperature   |  |                    | 1.5   |      |   |
|           |  | LMV824I (Quad)   |  | 1.0                | 1.3   | mA   |   |
|           |  | LMV824I, Over Temperature  |  |                    | 1.6   |      |   |

## 6.11 AC Electrical Characteristics 5V

Unless otherwise specified, all limits ensured for  $T_J = 25^\circ\text{C}$ .  $V^+ = 5\text{ V}$ ,  $V^- = 0\text{ V}$ ,  $V_{\text{CM}} = 2.0\text{ V}$ ,  $V_O = 2.5\text{ V}$  and  $R_L > 1\text{ M}\Omega$ . Temperature extremes are  $-40^\circ\text{C} \leq T_J \leq 85^\circ\text{C}$  for LMV821/822/824, and  $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$  for LMV822-Q1/LMV824-Q1/LMV824I.

| PARAMETER |                              | TEST CONDITIONS   | MIN <sup>(1)</sup> | TYP <sup>(2)</sup> | MAX <sup>(1)</sup> | UNIT                   |
|-----------|------------------------------|---|--------------------|--------------------|--------------------|------------------------|
| SR        | Slew Rate                    | See <sup>(3)</sup>  | 1.4                | 2.0                |                    | V/ $\mu\text{s}$ min   |
| GBW       | Gain-Bandwidth Product       |   |                    | 5.6                |                    | MHz                    |
| $\Phi_m$  | Phase Margin                 |   |                    | 67                 |                    | Deg.                   |
| $G_m$     | Gain Margin                  |   |                    | 15                 |                    | dB                     |
|           | Amp-to-Amp Isolation         | See <sup>(4)</sup>  |                    | 135                |                    | dB                     |
| $e_n$     | Input-Related Voltage Noise  | $f = 1\text{ kHz}$ , $V_{\text{CM}} = 1\text{ V}$   |                    | 24                 |                    | nV/ $\sqrt{\text{Hz}}$ |
| $i_n$     | Input-Referred Current Noise | $f = 1\text{ kHz}$  |                    | 0.25               |                    | pA/ $\sqrt{\text{Hz}}$ |
| THD       | Total Harmonic Distortion    | $f = 1\text{ kHz}$ , $A_V = -2$ ,<br>$R_L = 10\text{ k}\Omega$ , $V_O = 4.1\text{ V}_{\text{PP}}$ |                    | 0.01%              |                    |                        |

(1) All limits are ensured by testing or statistical analysis.

(2) Typical Values represent the most likely parametric norm.

(3)  $V^+ = 5\text{ V}$ . Connected as voltage follower with 3V step input. Number specified is the slower of the positive and negative slew rates.

(4) Input referred,  $V^+ = 5\text{ V}$  and  $R_L = 100\text{ k}\Omega$  connected to 2.5V. Each amp excited in turn with 1 kHz to produce  $V_O = 3\text{ V}_{\text{PP}}$ .

### 6.12 Typical Characteristics

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

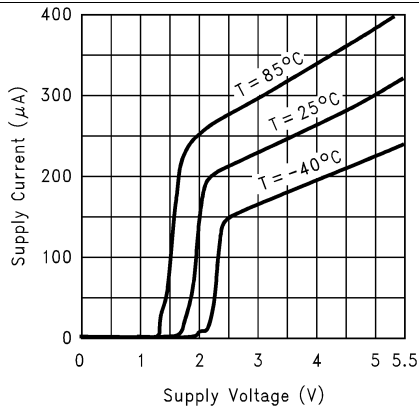


Figure 1. Supply Current vs. Supply Voltage (LMV821)

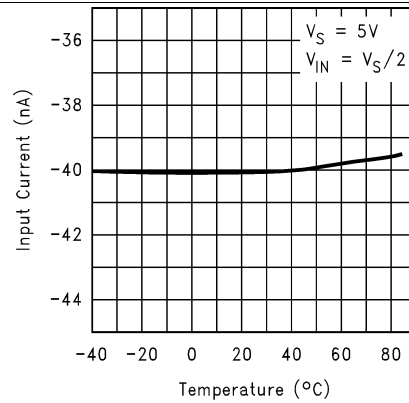


Figure 2. Input Current vs. Temperature

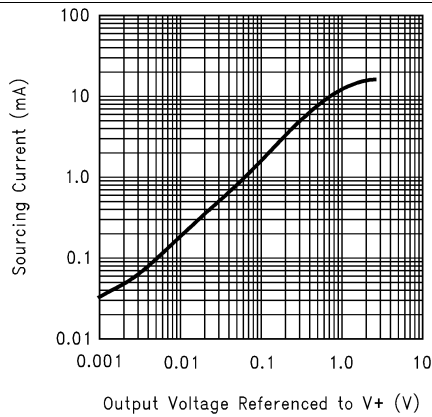


Figure 3. Sourcing Current vs. Output Voltage ( $V_S = 2.7V$ )

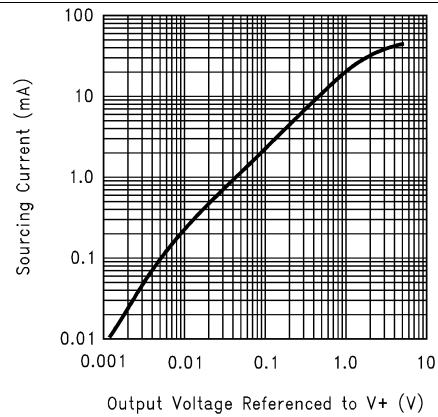


Figure 4. Sourcing Current vs. Output Voltage ( $V_S = 5V$ )

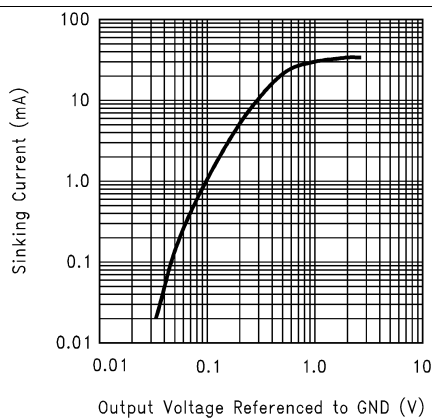


Figure 5. Sinking Current vs. Output Voltage ( $V_S = 2.7V$ )

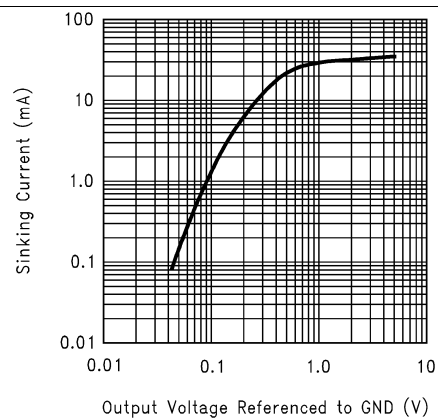
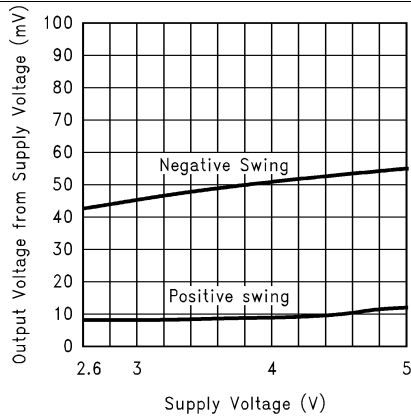


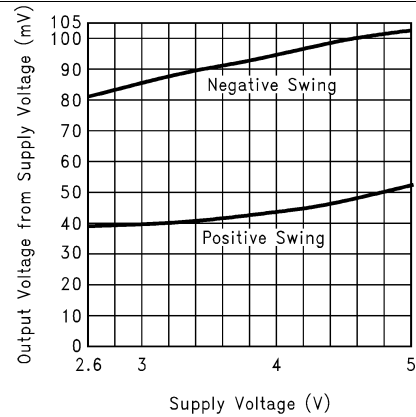
Figure 6. Sinking Current vs. Output Voltage ( $V_S = 5V$ )

### Typical Characteristics (continued)

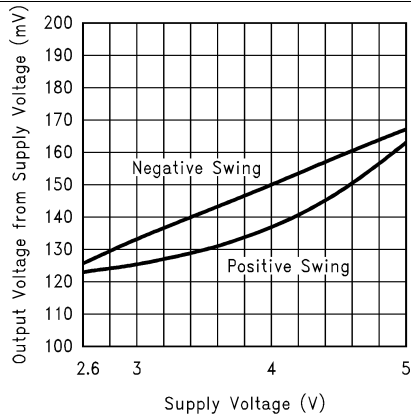
Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .



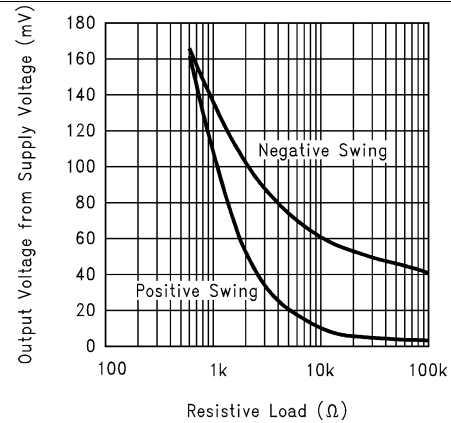
**Figure 7. Output Voltage Swing vs. Supply Voltage ( $R_L = 10k\Omega$ )**



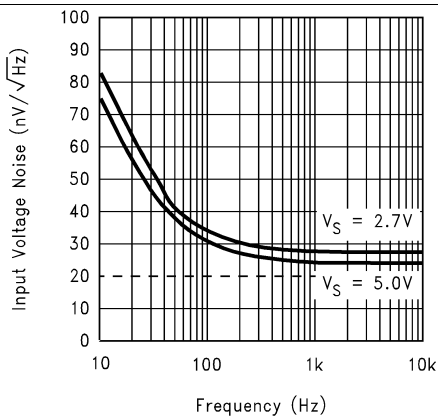
**Figure 8. Output Voltage Swing vs. Supply Voltage ( $R_L = 2k\Omega$ )**



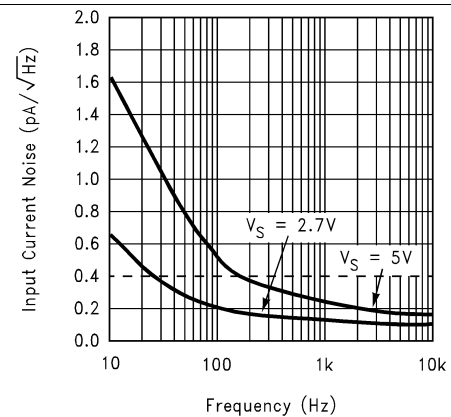
**Figure 9. Output Voltage Swing vs. Supply Voltage ( $R_L = 600\Omega$ )**



**Figure 10. Output Voltage Swing vs. Load Resistance**



**Figure 11. Input Voltage Noise vs. Frequency**



**Figure 12. Input Current Noise vs. Frequency**

Typical Characteristics (continued)

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

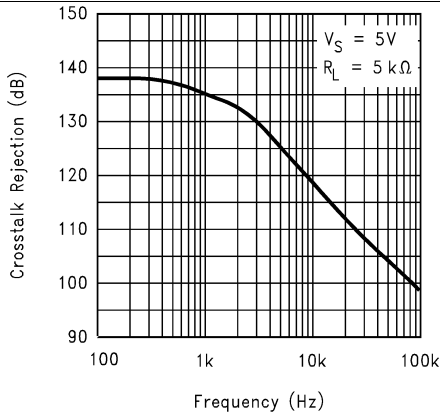


Figure 13. Crosstalk Rejection vs. Frequency

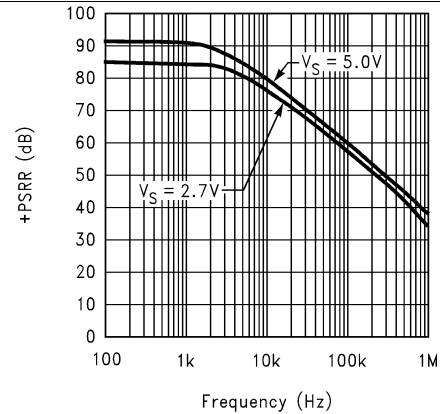


Figure 14. +PSRR vs. Frequency

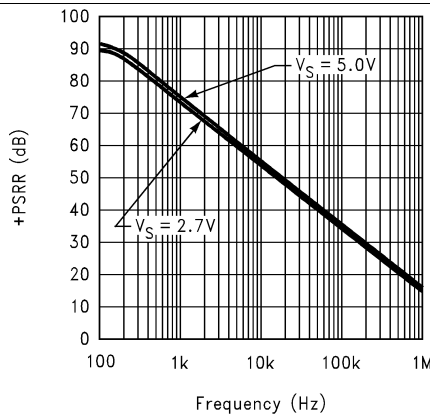


Figure 15. -PSRR vs. Frequency

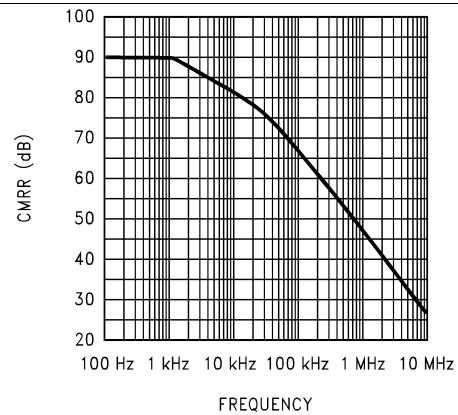


Figure 16. CMRR vs. Frequency

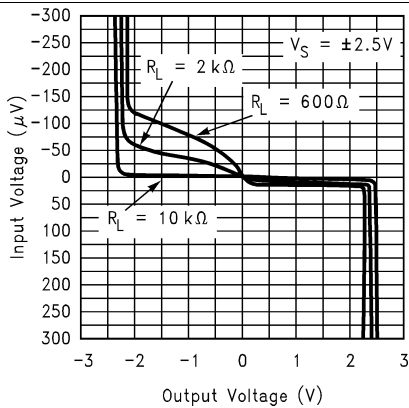


Figure 17. Input Voltage vs. Output Voltage

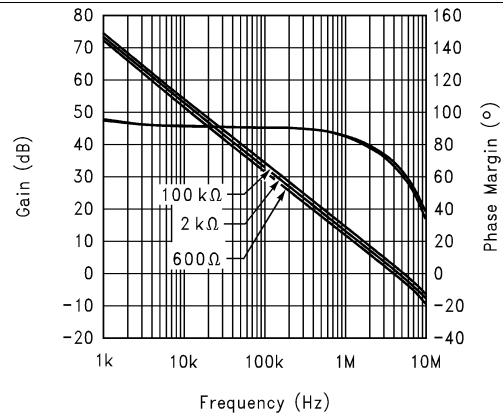
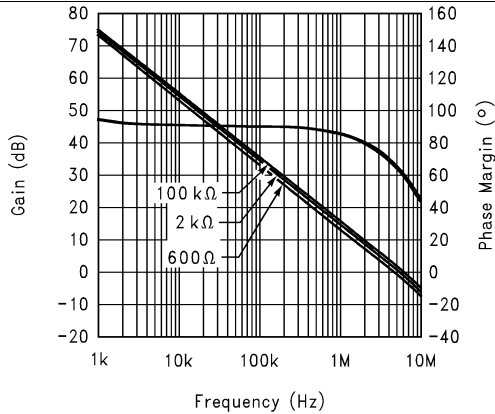


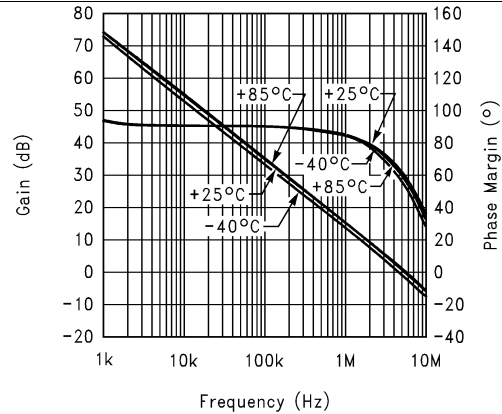
Figure 18. Gain and Phase Margin vs. Frequency ( $R_L = 100k\Omega, 2k\Omega, 600\Omega$ ) at 2.7V

### Typical Characteristics (continued)

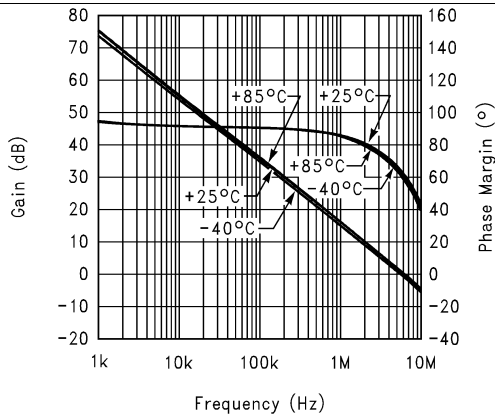
Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .



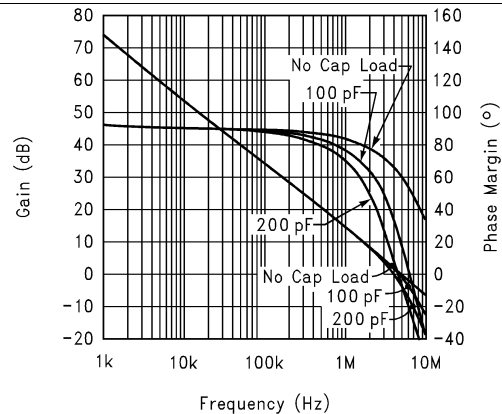
**Figure 19. Gain and Phase Margin vs. Frequency ( $R_L = 100k\Omega, 2k\Omega, 600\Omega$ ) at 5V**



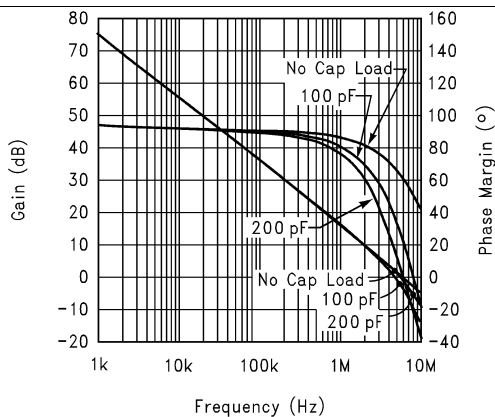
**Figure 20. Gain and Phase Margin vs. Frequency (Temp. = 25, -40, 85°C,  $R_L = 10k\Omega$ ) at 2.7V**



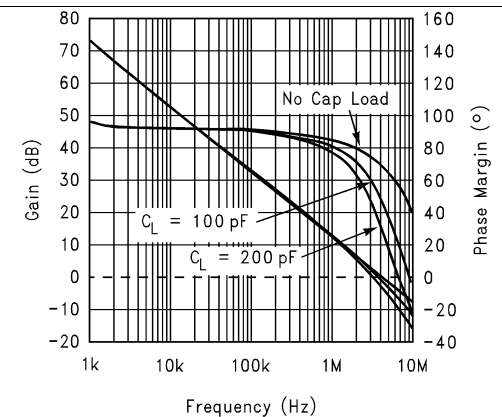
**Figure 21. Gain and Phase Margin vs. Frequency (Temp. = 25, -40, 85°C,  $R_L = 10k\Omega$ ) at 5V**



**Figure 22. Gain and Phase Margin vs. Frequency ( $C_L = 100pF, 200pF, 0pF, R_L = 10k\Omega$ ) at 2.7V**



**Figure 23. Gain and Phase Margin vs. Frequency ( $C_L = 100pF, 200pF, 0pF, R_L = 10k\Omega$ ) at 5V**



**Figure 24. Gain and Phase Margin vs. Frequency ( $C_L = 100pF, 200pF, 0pF, R_L = 600\Omega$ ) at 2.7V**



Typical Characteristics (continued)

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

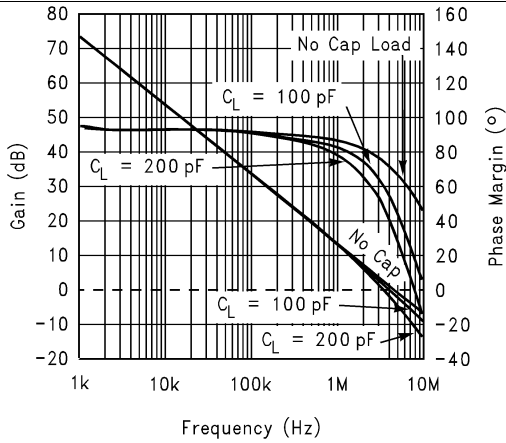


Figure 25. Gain and Phase Margin vs. Frequency ( $C_L = 100pF, 200pF, 0pF R_L = 600\Omega$ ) at 5V

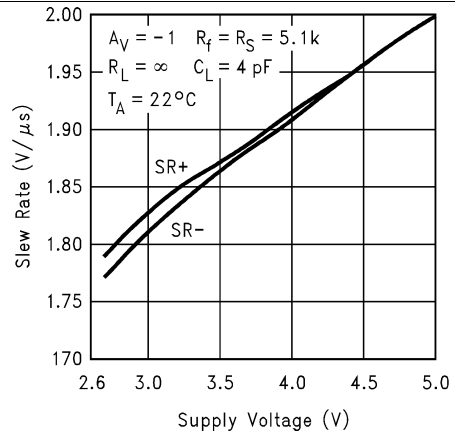


Figure 26. Slew Rate vs. Supply Voltage

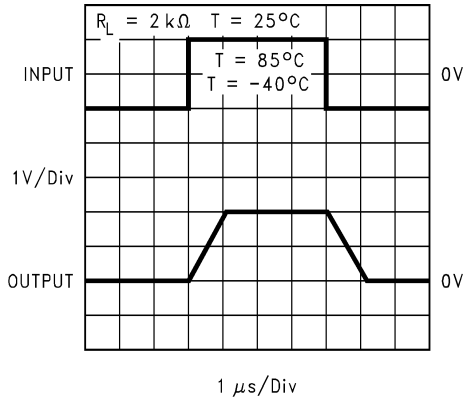


Figure 27. Non-Inverting Large Signal Pulse Response

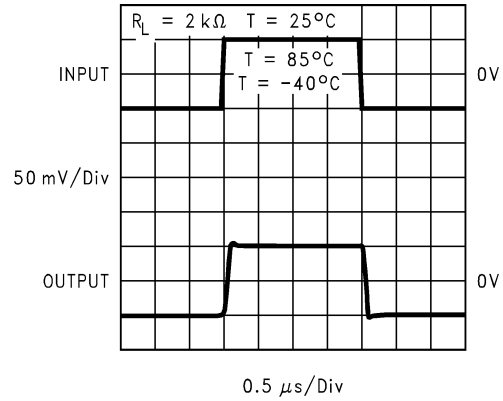


Figure 28. Non-Inverting Small Signal Pulse Response

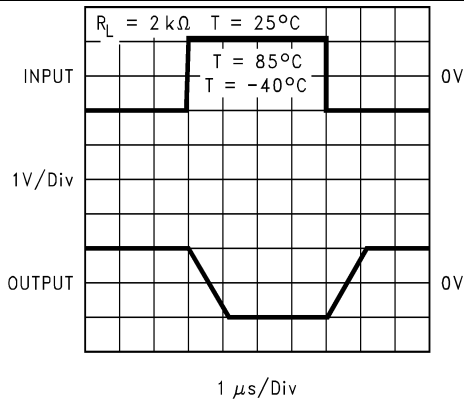


Figure 29. Inverting Large Signal Pulse Response

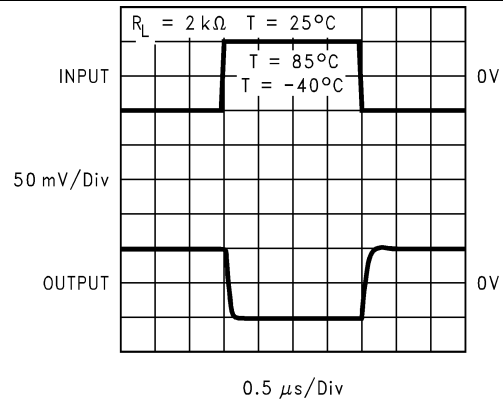
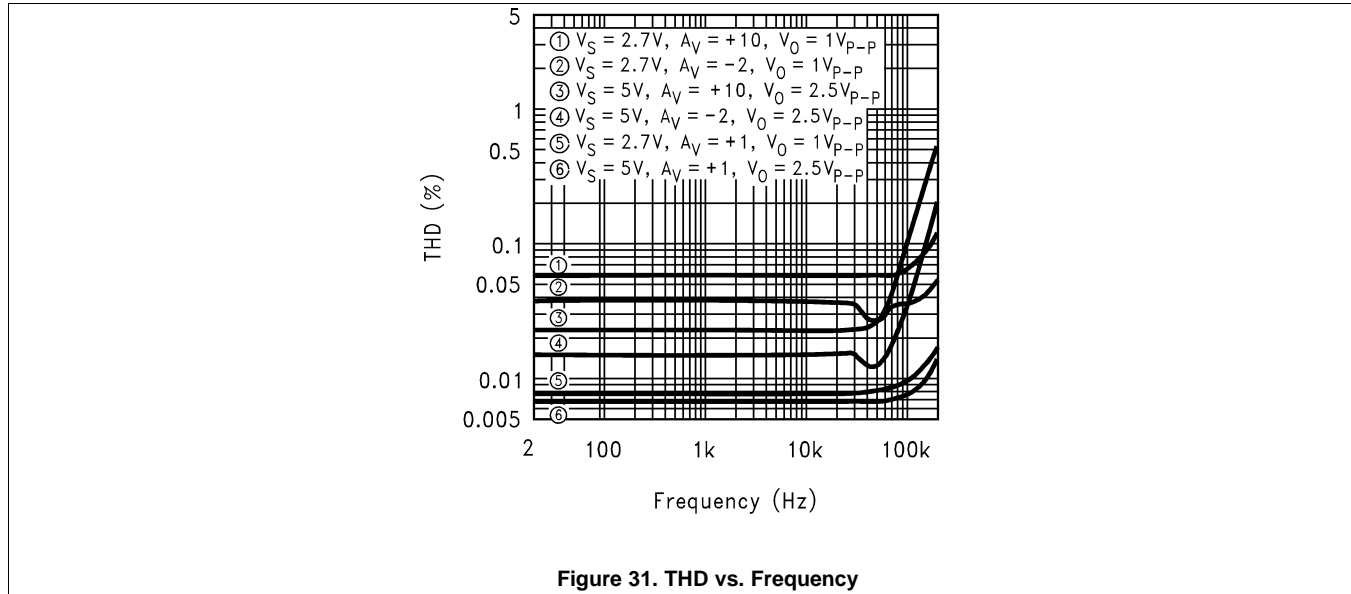


Figure 30. Inverting Small Signal Pulse Response

### Typical Characteristics (continued)

Unless otherwise specified,  $V_S = +5V$ , single supply,  $T_A = 25^\circ C$ .

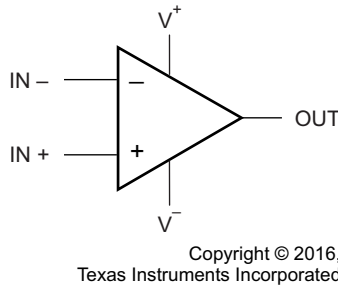


## 7 Detailed Description

### 7.1 Overview

The LMV821/LMV822/LMV824 bring performance and economy to low voltage / low power systems. With a 5 MHz unity-gain frequency and a specified 1.4 V/ $\mu$ s slew rate, the quiescent current is only 220  $\mu$ A/amplifier (2.7 V). They provide rail-to-rail (R-to-R) output swing into heavy loads (600  $\Omega$  specified). The input common-mode voltage range includes ground, and the maximum input offset voltage is 3.5 mV.

### 7.2 Functional Block Diagram



**Figure 32. (Each Amplifier)**

### 7.3 Feature Description

The amplifier's differential inputs consist of a non-inverting input (+IN) and an inverting input (–IN). The amplifier amplifies only the difference in voltage between the two inputs, which is called the differential input voltage. The output voltage of the op-amp  $V_{OUT}$  is given by [Equation 1](#):

$$V_{OUT} = A_{OL} (IN^+ - IN^-) \quad (1)$$

where  $A_{OL}$  is the open-loop gain of the amplifier, typically around 100dB (100,000x, or 10uV per Volt).

### 7.4 Device Functional Modes

This section covers the following design considerations:

1. Frequency and Phase Response Considerations
2. Unity-Gain Pulse Response Considerations
3. Input Bias Current Considerations

#### 7.4.1 Frequency and Phase Response Considerations

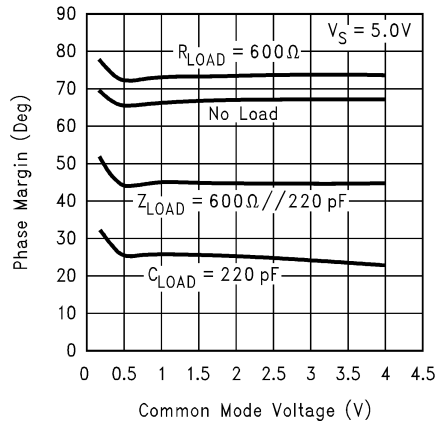
The relationship between open-loop frequency response and open-loop phase response determines the closed-loop stability performance (negative feedback). The open-loop phase response causes the feedback signal to shift towards becoming positive feedback, thus becoming unstable. The further the output phase angle is from the input phase angle, the more stable the negative feedback will operate. Phase Margin ( $\varphi_m$ ) specifies this output-to-input phase relationship at the unity-gain crossover point. Zero degrees of phase-margin means that the input and output are completely in phase with each other and will sustain oscillation at the unity-gain frequency.

The AC tables show  $\varphi_m$  for a no load condition. But  $\varphi_m$  changes with load. The Gain and Phase margin vs Frequency plots in the curve section can be used to graphically determine the  $\varphi_m$  for various loaded conditions. To do this, examine the phase angle portion of the plot, find the phase margin point at the unity-gain frequency, and determine how far this point is from zero degree of phase-margin. The larger the phase-margin, the more stable the circuit operation.

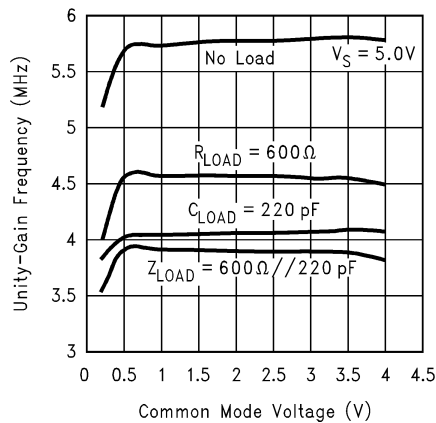
### Device Functional Modes (continued)

The bandwidth is also affected by load. The graphs of [Figure 33](#) and [Figure 34](#) provide a quick look at how various loads affect the  $\phi_m$  and the bandwidth of the LMV821/822/824 family. These graphs show capacitive loads reducing both  $\phi_m$  and bandwidth, while resistive loads reduce the bandwidth but increase the  $\phi_m$ . Notice how a 600Ω resistor can be added in parallel with 220 picofarads capacitance, to increase the  $\phi_m$  20°(approx.), but at the price of about a 100 kHz of bandwidth.

Overall, the LMV821/822/824 family provides good stability for loaded condition.



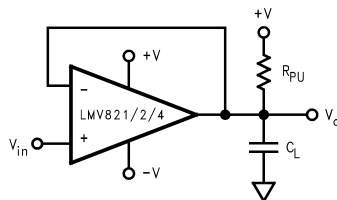
**Figure 33. Phase Margin vs Common Mode Voltage for Various Loads**



**Figure 34. Unity-Gain Frequency vs Common Mode Voltage for Various Loads**

#### 7.4.2 Unity Gain Pulse Response Consideration

A pull-up resistor is well suited for increasing unity-gain, pulse response stability. For example, a 600 Ω pull-up resistor reduces the overshoot voltage by about 50%, when driving a 220 pF load. [Figure 35](#) shows how to implement the pull-up resistor for more pulse response stability.



**Figure 35. Using a Pull-up Resistor at the Output for Stabilizing Capacitive Loads**

### Device Functional Modes (continued)

Higher capacitances can be driven by decreasing the value of the pull-up resistor, but its value shouldn't be reduced beyond the sinking capability of the part. An alternate approach is to use an isolation resistor as illustrated in Figure 36.

Figure 37 shows the resulting pulse response from a LMV824, while driving a 10,000 pF load through a 20Ω isolation resistor.

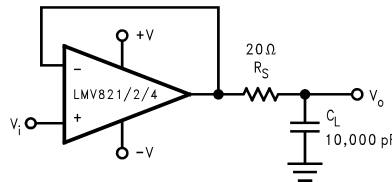


Figure 36. Using an Isolation Resistor to Drive Heavy Capacitive Loads

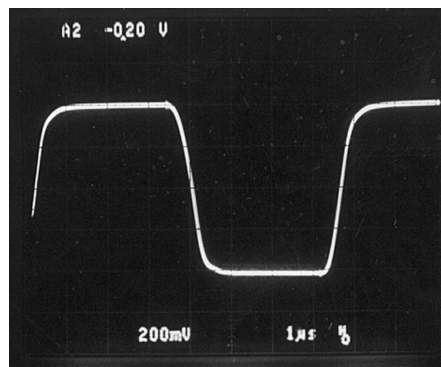
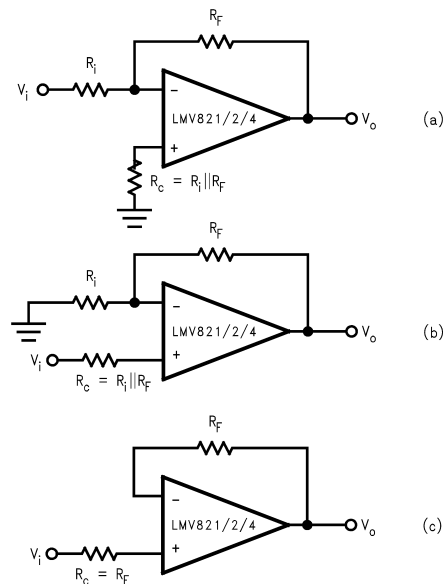


Figure 37. Pulse Response per Figure 36

#### 7.4.3 Input Bias Current Consideration

Input bias current ( $I_B$ ) can develop a somewhat significant offset voltage. This offset is primarily due to  $I_B$  flowing through the negative feedback resistor,  $R_F$ . For example, if  $I_B$  is 90 nA (max @ room) and  $R_F$  is 100 kΩ, then an offset of 9 mV will be developed ( $V_{OS} = I_B \times R_F$ ). Using a compensation resistor ( $R_C$ ), as shown in Figure 38, cancels out this affect. But the input offset current ( $I_{OS}$ ) will still contribute to an offset voltage in the same manner - typically 0.05 mV at room temp.

## Device Functional Modes (continued)



**Figure 38. Canceling the Voltage Offset Effect of Input Bias Current**

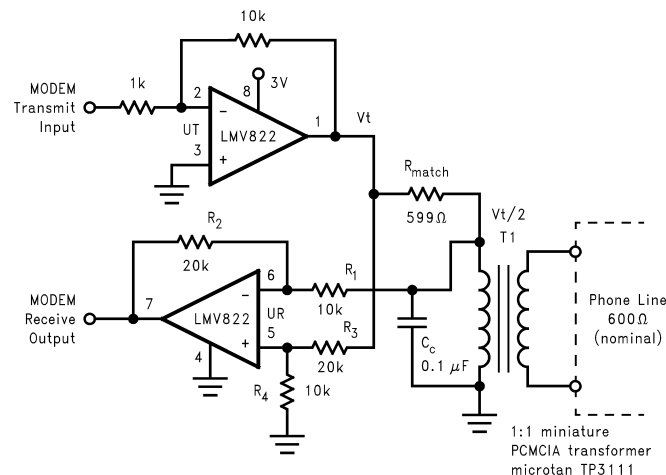
## 8 Application and Implementation

### 8.1 Application Information

The LMV82x bring performance and economy to low voltage/low power systems. They provide rail-to-rail output swing into heavy loads and are capable of driving large capacitive loads.

### 8.2 Typical Applications

#### 8.2.1 Telephone-Line Transceiver



**Figure 39. Telephone-Line Transceiver for a PCMCIA Modem Card**

## Typical Applications (continued)

### 8.2.1.1 Design Requirements

The telephone-line transceiver of Figure 39 provides a full-duplexed connection through a PCMCIA, miniature transformer. The differential configuration of receiver portion (UR), cancels reception from the transmitter portion (UT). Note that the input signals for the differential configuration of UR, are the transmit voltage ( $V_T$ ) and  $V_T/2$ . This is because  $R_{match}$  is chosen to match the coupled telephone-line impedance; therefore dividing  $V_T$  by two (assuming  $R_1 \gg R_{match}$ ).

### 8.2.1.2 Detailed Design Procedure

The differential configuration of UR has its resistors chosen to cancel the  $V_T$  and  $V_T/2$  inputs according to the following equation:

$$V_o = V_T \left( \frac{R_4}{R_3 + R_4} \right) \left( 1 + \frac{R_2}{R_1} \right) - \frac{V_T}{2} \left( \frac{R_2}{R_1} \right) = V_T \frac{1}{3} (3) - \frac{V_T}{2} (2) = 0 \quad (2)$$

Note that  $C_c$  is included for canceling out the inadequacies of the lossy, miniature transformer.

### 8.2.2 “Simple” Mixer (Amplitude Modulator)

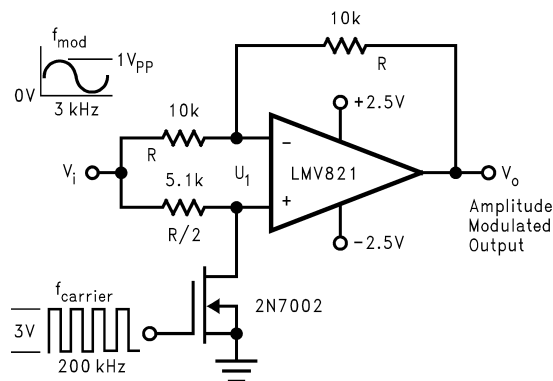


Figure 40. Amplitude Modulator Circuit

#### 8.2.2.1 Design Requirements

The simple mixer can be applied to applications that utilize the Doppler Effect to measure the velocity of an object. The difference frequency is one of its output frequency components. This difference frequency magnitude ( $|F_M - F_C|$ ) is the key factor for determining an object's velocity per the Doppler Effect. If a signal is transmitted to a moving object, the reflected frequency will be a different frequency. This difference in transmit and receive frequency is directly proportional to an object's velocity.

#### 8.2.2.2 Detailed Design Procedure

The mixer of Figure 40 is simple and provides a unique form of amplitude modulation.  $V_i$  is the modulation frequency ( $F_M$ ), while a +3V square-wave at the gate of Q1, induces a carrier frequency ( $F_C$ ). Q1 switches (toggles) U1 between inverting and non-inverting unity gain configurations. Offsetting a sine wave above ground at  $V_i$  results in the oscilloscope photo of Figure 41.

## Typical Applications (continued)

### 8.2.2.3 Application Performance Plot

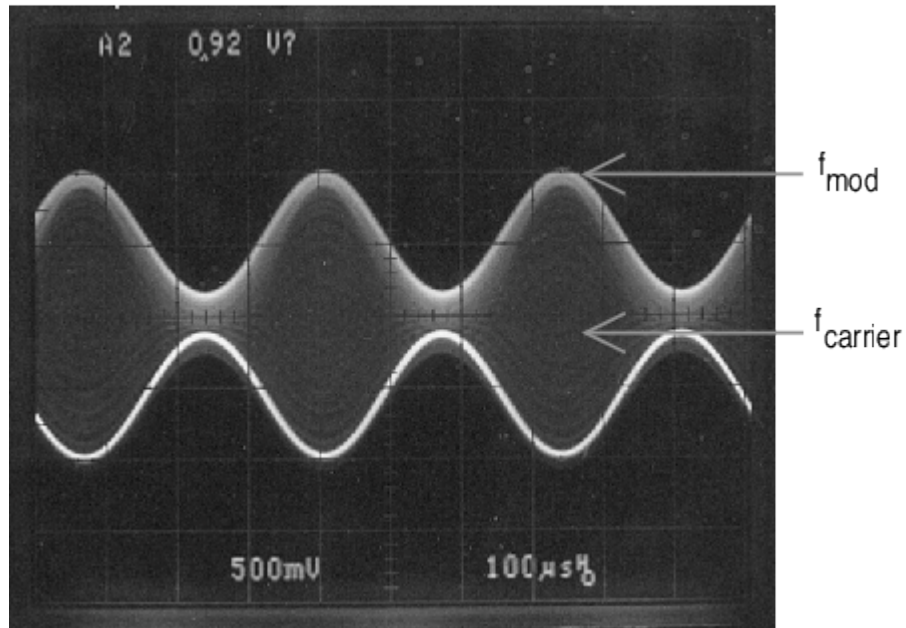


Figure 41. Output signal of Figure 40

### 8.2.3 Tri-Level Voltage Detector

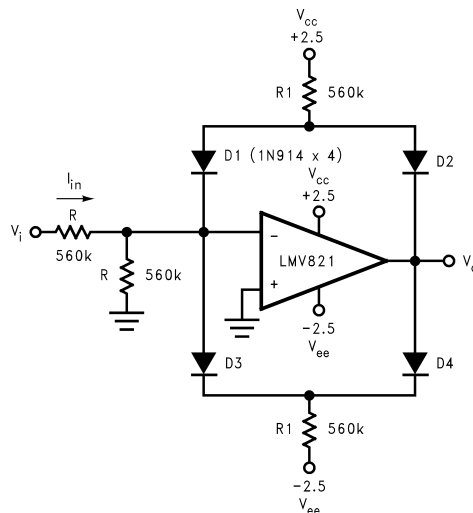


Figure 42. Tri-level Voltage Detector

#### 8.2.3.1 Design Requirements

The tri-level voltage detector of Figure 42 provides a type of window comparator function. It detects three different input voltage ranges: Min-range, Mid-range, and Max-range. The output voltage ( $V_O$ ) is at  $V_{CC}$  for the Min-range.  $V_O$  is clamped at GND for the Mid-range. For the Max-range,  $V_O$  is at  $V_{EE}$ . Figure 43 shows a  $V_O$  vs.  $V_I$  oscilloscope photo per the circuit of Figure 42.



### Typical Applications (continued)

Its operation is as follows:  $V_I$  deviating from GND, causes the diode bridge to absorb  $I_{IN}$  to maintain a clamped condition ( $V_O = 0V$ ). Eventually,  $I_{IN}$  reaches the bias limit of the diode bridge. When this limit is reached, the clamping effect stops and the op amp responds open loop. The design equation directly preceding Figure 43, shows how to determine the clamping range. The equation solves for the input voltage band on each side GND. The mid-range is twice this voltage band.

#### 8.2.3.2 Detailed Design Procedure

$$\Delta V = \frac{R}{R_1} (V_{CC} - V_{Diode}) \tag{3}$$

#### 8.2.3.3 Application Performance Plot

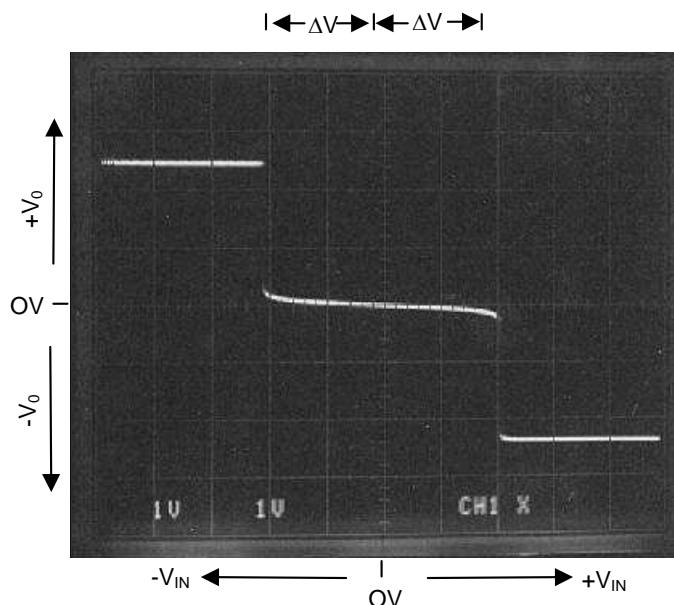
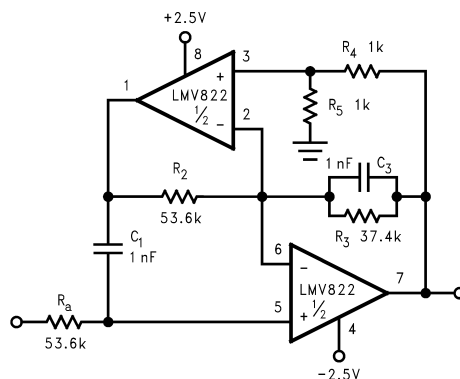


Figure 43. X, Y Oscilloscope Trace showing  $V_{OUT}$  vs  $V_{IN}$  per the Circuit of Tri-Level Voltage Detector

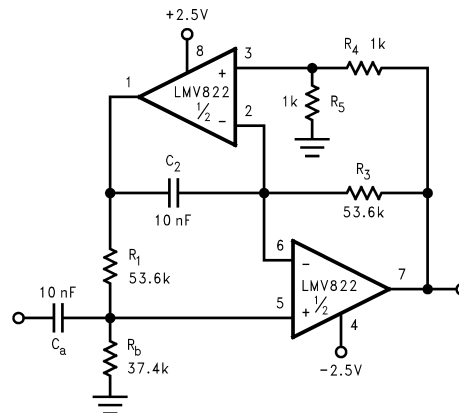
#### 8.2.4 Dual Amplifier Active Filters (DAAFs)



3 kHz Low-Pass Active Filter with a Butterworth Response and a Pass Band Gain of Times Two

Figure 44. Dual Amplifier Active Low-Pass Filter

## Typical Applications (continued)



300 Hz High-Pass Active Filter with a Butterworth Response and a Pass Band Gain of Times Two

**Figure 45. Dual Active Amplifier High-Pass Filter**

### 8.2.4.1 Design Requirements

The LMV822/24 bring economy and performance to DAAFs. The low-pass and the high-pass filters of [Figure 44](#) and [Figure 45](#) (respectively), offer one key feature: excellent sensitivity performance. Good sensitivity is when deviations in component values cause relatively small deviations in a filter's parameter such as cutoff frequency ( $F_c$ ). Single amplifier active filters like the Sallen-Key provide relatively poor sensitivity performance that sometimes cause problems for high production runs; their parameters are much more likely to deviate out of specification than a DAAF would. The DAAFs of [Figure 44](#) and [Figure 45](#) are well suited for high volume production.

### 8.2.4.2 Detailed Design Procedure

Active filters are also sensitive to an op amp's parameters -Gain and Bandwidth, in particular. The LMV822/24 provide a large gain and wide bandwidth. And DAAFs make excellent use of these feature specifications.

Single Amplifier versions require a large open-loop to closed-loop gain ratio - approximately 50 to 1, at the  $F_c$  of the filter response.

In addition to performance, DAAFs are relatively easy to design and implement. The design equations for the low-pass and high-pass DAAFs are shown below. The first two equations calculate the  $F_c$  and the circuit Quality Factor (Q) for the LPF ([Figure 44](#)). The second two equations calculate the  $F_c$  and Q for the HPF ([Figure 45](#)).

$$\begin{aligned}
 \text{(LPF)} \quad F_c &= \frac{\sqrt{R_5}}{2\pi \sqrt{R_a} \cdot \sqrt{R_2} \cdot \sqrt{R_4} \cdot \sqrt{C_1} \cdot \sqrt{C_3}} \\
 Q &= 2\pi F_c \sqrt{C_1} \cdot \sqrt{C_3} \\
 \text{(HPF)} \quad F_c &= \frac{\sqrt{R_4}}{2\pi \sqrt{R_1} \cdot \sqrt{R_3} \cdot \sqrt{R_5} \cdot \sqrt{C_a} \cdot \sqrt{C_2}} \\
 Q &= 2\pi F_c \sqrt{C_a} \cdot \sqrt{C_2}
 \end{aligned} \tag{4}$$

To simplify the design process, certain components are set equal to each other. Refer to [Figure 44](#) and [Figure 45](#). These equal component values help to simplify the design equations as follows:

$$\begin{aligned}
 \text{(LPF)} \quad R_a &= R_2 = \frac{1}{2\pi F_c \sqrt{C_1} \cdot \sqrt{C_3}} \\
 R_3 &= \frac{Q}{2\pi F_c \sqrt{C_1} \cdot \sqrt{C_3}} \\
 \text{(HPF)} \quad R_1 &= R_3 = \frac{1}{2\pi F_c \sqrt{C_a} \cdot \sqrt{C_2}} \\
 R_b &= \frac{Q}{2\pi F_c \sqrt{C_a} \cdot \sqrt{C_2}}
 \end{aligned} \tag{5}$$

**Typical Applications (continued)**

To illustrate the design process/implementation, a 3 kHz, Butterworth response, low-pass filter DAAF (Figure 44) is designed as follows:

1. Choose  $C_1 = C_3 = C = 1 \text{ nF}$
2. Choose  $R_4 = R_5 = 1 \text{ k}\Omega$
3. Calculate  $R_a$  and  $R_2$  for the desired  $F_c$  as follows:

$$\begin{aligned}
 R_a = R_2 &= \frac{1}{2\pi(F_c)C} \\
 &= \frac{1}{2\pi(3 \text{ kHz})1\text{nF}} \\
 &= 53.1 \text{ k}\Omega \\
 &\cong 53.6 \text{ k}\Omega \text{ (Practical Value)}
 \end{aligned}
 \tag{6}$$

4. Calculate  $R_3$  for the desired Q. The desired Q for a Butterworth (Maximally Flat) response is 0.707 (45 degrees into the s-plane).  $R_3$  calculates as follows:

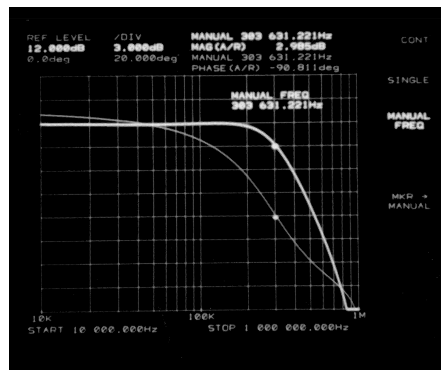
$$\begin{aligned}
 R_3 &= \frac{Q}{2\pi(F_c)C} \\
 &= \frac{0.707}{2\pi(3 \text{ kHz})1\text{nF}} \\
 &= 37.5 \text{ k}\Omega \\
 &\cong 37.4 \text{ k}\Omega \text{ (Practical Value)}
 \end{aligned}
 \tag{7}$$

Notice that  $R_3$  could also be calculated as 0.707 of  $R_a$  or  $R_2$ .

The circuit was implemented and its cutoff frequency measured. The cutoff frequency measured at 2.92 kHz.

The circuit also showed good repeatability. Ten different LMV822 samples were placed in the circuit. The corresponding change in the cutoff frequency was less than a percent.

**8.2.4.3 Application Performance Plots**



Butterworth Response as Measured by the HP3577A Network Analyzer

**Figure 46. 300 kHz, DAAF Low-Pass Filter Measurement Results**

Figure 46 shows an impressive photograph of a network analyzer measurement (HP3577A). The measurement was taken from a 300 kHz version of Figure 44. At 300 kHz, the open-loop to closed-loop gain ratio @  $F_c$  is about 5 to 1. This is 10 times lower than the 50 to 1 “rule of thumb” for Single Amplifier Active Filters.

Table 1 provides sensitivity measurements for a 10 M $\Omega$  load condition. The left column shows the passive components for the 3 kHz low-pass DAAF. The third column shows the components for the 300 Hz high-pass DAAF. Their respective sensitivity measurements are shown to the right of each component column. Their values consists of the percent change in cutoff frequency ( $F_c$ ) divided by the percent change in component value. The lower the sensitivity value, the better the performance.

## Typical Applications (continued)

Each resistor value was changed by about 10 percent, and this measured change was divided into the measured change in  $F_c$ . A positive or negative sign in front of the measured value, represents the direction  $F_c$  changes relative to components' direction of change. For example, a sensitivity value of negative 1.2, means that for a 1 percent increase in component value,  $F_c$  decreases by 1.2 percent.

Note that this information provides insight on how to fine tune the cutoff frequency, if necessary. It should be also noted that  $R_4$  and  $R_5$  of each circuit also caused variations in the pass band gain. Increasing  $R_4$  by ten percent, increased the gain by 0.4 dB, while increasing  $R_5$  by ten percent, decreased the gain by 0.4 dB.

**Table 1. Component Sensitivity Measurements**

| Component (LPF) | Sensitivity (LPF) | Component (HPF) | Sensitivity (HPF) |
|-----------------|-------------------|-----------------|-------------------|
| $R_a$           | -1.2              | $C_a$           | -0.7              |
| $C_1$           | -0.1              | $R_b$           | -1.0              |
| $R_2$           | -1.1              | $R_1$           | +0.1              |
| $R_3$           | +0.7              | $C_2$           | -0.1              |
| $C_3$           | -1.5              | $R_3$           | +0.1              |
| $R_4$           | -0.6              | $R_4$           | -0.1              |
| $R_5$           | +0.6              | $R_5$           | +0.1              |

### 8.3 Do's and Don'ts

Do properly bypass the power supplies.

Do add series resistance to the output when driving capacitive loads, particularly cables, Muxes and ADC inputs.

Do not exceed the input common mode range. The input is not "Rail to Rail" and will limit upper output swing when configured as followers or other low-gain applications. See the Input Common Mode Voltage Range section of the Electrical Table.

Do add series current limiting resistors and external schottky clamp diodes if input voltage is expected to exceed the supplies. Limit the current to 1mA or less (1K $\Omega$  per volt).

## 9 Power Supply Recommendations

For proper operation, the power supplies must be properly decoupled. For decoupling the supply lines it is suggested that 10 nF capacitors be placed as close as possible to the op amp power supply pins. For single supply, place a capacitor between  $V^+$  and  $V^-$  supply leads. For dual supplies, place one capacitor between  $V^+$  and ground, and one capacitor between  $V^-$  and ground.

## 10 Layout

### 10.1 Layout Guidelines

The V+ pin should be bypassed to ground with a low ESR capacitor.

The optimum placement is closest to the V+ and ground pins.

Care should be taken to minimize the loop area formed by the bypass capacitor connection between V+ and ground.

The ground pin should be connected to the PCB ground plane at the pin of the device.

The feedback components should be placed as close to the device as possible minimizing strays.

### 10.2 Layout Example

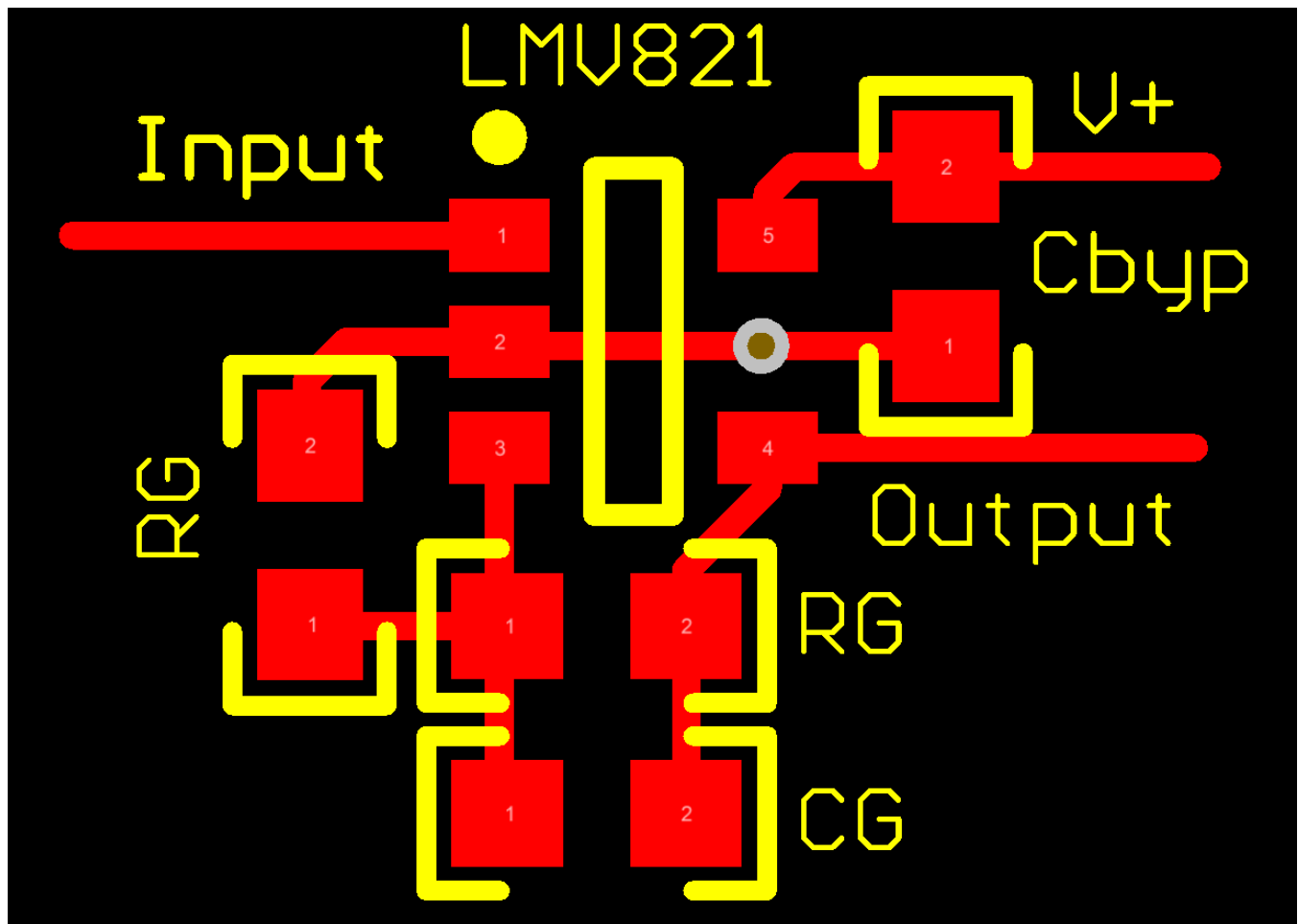


Figure 47. 2-D Layout

Layout Example (continued)

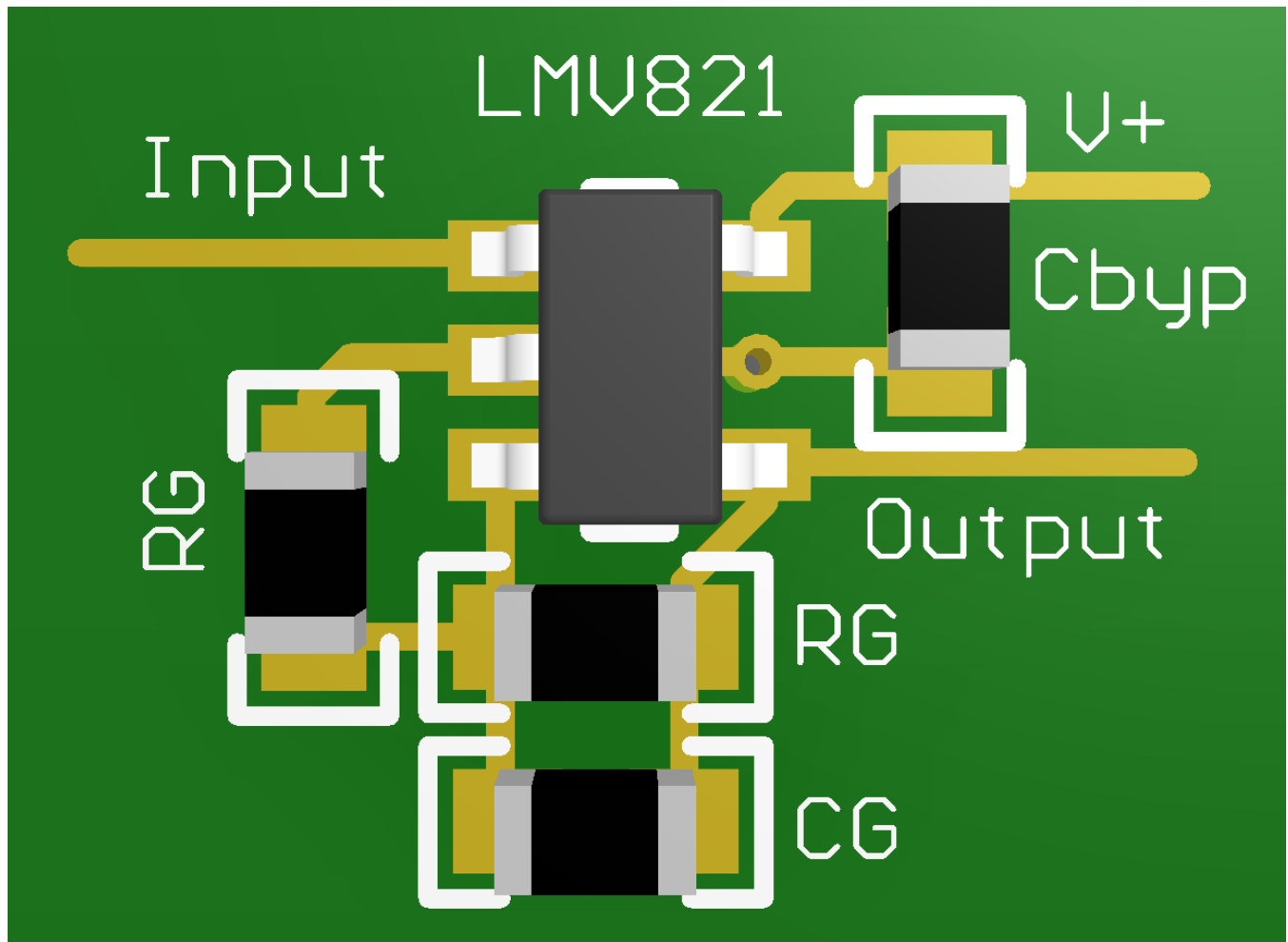


Figure 48. 3-D Layout

## 11 Device and Documentation Support

### 11.1 Documentation Support

#### 11.1.1 Related Documentation

For related documentation see the following:

- [TI Filterpro Software](#)
- [TI Universal Operational Amplifier Evaluation Module](#)
- [TINA-TI SPICE-Based Analog Simulation Program](#)

#### 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 11.4 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 2. Related Links**

| PARTS       | PRODUCT FOLDER             | SAMPLE & BUY               | TECHNICAL DOCUMENTS        | TOOLS & SOFTWARE           | SUPPORT & COMMUNITY        |
|-------------|----------------------------|----------------------------|----------------------------|----------------------------|----------------------------|
| LMV821-N    | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| LMV822-N    | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| LMV822-N-Q1 | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| LMV824-N    | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| LMV824-N-Q1 | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |

#### 11.5 Trademarks

E2E is a trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

#### 11.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 11.7 Glossary

**SLYZ022** — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan<br>(2)  | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|------------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| LMV821M5         | LIFEBUY       | SOT-23       | DBV             | 5    | 1000        | Non-RoHS & Green | Call TI                              | Level-1-260C-UNLIM   | -40 to 85    | A14                     |         |
| LMV821M5/NOPB    | ACTIVE        | SOT-23       | DBV             | 5    | 1000        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | A14                     | Samples |
| LMV821M5X        | LIFEBUY       | SOT-23       | DBV             | 5    | 3000        | Non-RoHS & Green | Call TI                              | Level-1-260C-UNLIM   | -40 to 85    | A14                     |         |
| LMV821M5X/NOPB   | ACTIVE        | SOT-23       | DBV             | 5    | 3000        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | A14                     | Samples |
| LMV821M7         | LIFEBUY       | SC70         | DCK             | 5    | 1000        | Non-RoHS & Green | Call TI                              | Level-1-260C-UNLIM   | -40 to 85    | A15                     |         |
| LMV821M7/NOPB    | ACTIVE        | SC70         | DCK             | 5    | 1000        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | A15                     | Samples |
| LMV821M7X/NOPB   | ACTIVE        | SC70         | DCK             | 5    | 3000        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | A15                     | Samples |
| LMV822M          | LIFEBUY       | SOIC         | D               | 8    | 95          | Non-RoHS & Green | Call TI                              | Level-1-235C-UNLIM   | -40 to 85    | LMV<br>822M             |         |
| LMV822M/NOPB     | ACTIVE        | SOIC         | D               | 8    | 95          | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | LMV<br>822M             | Samples |
| LMV822MM         | LIFEBUY       | VSSOP        | DGK             | 8    | 1000        | Non-RoHS & Green | Call TI                              | Level-1-260C-UNLIM   | -40 to 85    | V822                    |         |
| LMV822MM/NOPB    | ACTIVE        | VSSOP        | DGK             | 8    | 1000        | RoHS & Green     | NIPDAUAG   SN                        | Level-1-260C-UNLIM   | -40 to 85    | V822                    | Samples |
| LMV822MMX/NOPB   | ACTIVE        | VSSOP        | DGK             | 8    | 3500        | RoHS & Green     | NIPDAUAG   SN                        | Level-1-260C-UNLIM   | -40 to 85    | V822                    | Samples |
| LMV822MX         | LIFEBUY       | SOIC         | D               | 8    | 2500        | Non-RoHS & Green | Call TI                              | Level-1-235C-UNLIM   | -40 to 85    | LMV<br>822M             |         |
| LMV822MX/NOPB    | ACTIVE        | SOIC         | D               | 8    | 2500        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | LMV<br>822M             | Samples |
| LMV822Q1MM/NOPB  | ACTIVE        | VSSOP        | DGK             | 8    | 1000        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | AKAA                    | Samples |
| LMV822Q1MMX/NOPB | ACTIVE        | VSSOP        | DGK             | 8    | 3500        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | AKAA                    | Samples |
| LMV824M/NOPB     | ACTIVE        | SOIC         | D               | 14   | 55          | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | LMV824M                 | Samples |
| LMV824MT/NOPB    | ACTIVE        | TSSOP        | PW              | 14   | 94          | RoHS & Green     | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 85    | LMV824<br>MT            | Samples |

| Orderable Device | Status<br>(1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan<br>(2)  | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|-----------------|------|-------------|------------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| LMV824MTX        | LIFEBUY       | TSSOP        | PW              | 14   | 2500        | Non-RoHS & Green | Call TI                              | Level-1-260C-UNLIM   | -40 to 85    | LMV824 MT               |                         |
| LMV824MTX/NOPB   | ACTIVE        | TSSOP        | PW              | 14   | 2500        | RoHS & Green     | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 85    | LMV824 MT               | <a href="#">Samples</a> |
| LMV824MX/NOPB    | ACTIVE        | SOIC         | D               | 14   | 2500        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 85    | LMV824M                 | <a href="#">Samples</a> |
| LMV824NDGVR      | ACTIVE        | TVSOP        | DGV             | 14   | 2000        | RoHS & Green     | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 125   | MV824N                  | <a href="#">Samples</a> |
| LMV824Q1MA/NOPB  | ACTIVE        | SOIC         | D               | 14   | 55          | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | LMV824Q1 MA             | <a href="#">Samples</a> |
| LMV824Q1MAX/NOPB | ACTIVE        | SOIC         | D               | 14   | 2500        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | LMV824Q1 MA             | <a href="#">Samples</a> |
| LMV824Q1MT/NOPB  | ACTIVE        | TSSOP        | PW              | 14   | 94          | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | LMV824 Q1MT             | <a href="#">Samples</a> |
| LMV824Q1MTX/NOPB | ACTIVE        | TSSOP        | PW              | 14   | 2500        | RoHS & Green     | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | LMV824 Q1MT             | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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**OTHER QUALIFIED VERSIONS OF LMV822-N, LMV822-N-Q1, LMV824-N, LMV824-N-Q1 :**

- Catalog : [LMV822-N](#), [LMV824-N](#)
- Automotive : [LMV822-N-Q1](#), [LMV824-N-Q1](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LMV821M5         | SOT-23       | DBV             | 5    | 1000 | 178.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| LMV821M5/NOPB    | SOT-23       | DBV             | 5    | 1000 | 178.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| LMV821M5X        | SOT-23       | DBV             | 5    | 3000 | 178.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| LMV821M5X/NOPB   | SOT-23       | DBV             | 5    | 3000 | 178.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| LMV821M7         | SC70         | DCK             | 5    | 1000 | 178.0              | 8.4                | 2.25    | 2.45    | 1.2     | 4.0     | 8.0    | Q3            |
| LMV821M7/NOPB    | SC70         | DCK             | 5    | 1000 | 178.0              | 8.4                | 2.25    | 2.45    | 1.2     | 4.0     | 8.0    | Q3            |
| LMV821M7X/NOPB   | SC70         | DCK             | 5    | 3000 | 178.0              | 8.4                | 2.25    | 2.45    | 1.2     | 4.0     | 8.0    | Q3            |
| LMV822MM         | VSSOP        | DGK             | 8    | 1000 | 178.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| LMV822MM/NOPB    | VSSOP        | DGK             | 8    | 1000 | 178.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| LMV822MMX/NOPB   | VSSOP        | DGK             | 8    | 3500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| LMV822MX         | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.5     | 5.4     | 2.0     | 8.0     | 12.0   | Q1            |
| LMV822MX/NOPB    | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.5     | 5.4     | 2.0     | 8.0     | 12.0   | Q1            |
| LMV822Q1MM/NOPB  | VSSOP        | DGK             | 8    | 1000 | 178.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| LMV822Q1MMX/NOPB | VSSOP        | DGK             | 8    | 3500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| LMV824MTX        | TSSOP        | PW              | 14   | 2500 | 330.0              | 12.4               | 6.95    | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| LMV824MTX/NOPB   | TSSOP        | PW              | 14   | 2500 | 330.0              | 12.4               | 6.95    | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |

| Device           | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LMV824MX/NOPB    | SOIC         | D               | 14   | 2500 | 330.0              | 16.4               | 6.5     | 9.35    | 2.3     | 8.0     | 16.0   | Q1            |
| LMV824NDGVR      | TVSOP        | DGV             | 14   | 2000 | 330.0              | 12.4               | 6.8     | 4.0     | 1.6     | 8.0     | 12.0   | Q1            |
| LMV824Q1MAX/NOPB | SOIC         | D               | 14   | 2500 | 330.0              | 16.4               | 6.5     | 9.35    | 2.3     | 8.0     | 16.0   | Q1            |
| LMV824Q1MTX/NOPB | TSSOP        | PW              | 14   | 2500 | 330.0              | 12.4               | 6.95    | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LMV821M5         | SOT-23       | DBV             | 5    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV821M5/NOPB    | SOT-23       | DBV             | 5    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV821M5X        | SOT-23       | DBV             | 5    | 3000 | 208.0       | 191.0      | 35.0        |
| LMV821M5X/NOPB   | SOT-23       | DBV             | 5    | 3000 | 208.0       | 191.0      | 35.0        |
| LMV821M7         | SC70         | DCK             | 5    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV821M7/NOPB    | SC70         | DCK             | 5    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV821M7X/NOPB   | SC70         | DCK             | 5    | 3000 | 208.0       | 191.0      | 35.0        |
| LMV822MM         | VSSOP        | DGK             | 8    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV822MM/NOPB    | VSSOP        | DGK             | 8    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV822MMX/NOPB   | VSSOP        | DGK             | 8    | 3500 | 367.0       | 367.0      | 35.0        |
| LMV822MX         | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| LMV822MX/NOPB    | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| LMV822Q1MM/NOPB  | VSSOP        | DGK             | 8    | 1000 | 208.0       | 191.0      | 35.0        |
| LMV822Q1MMX/NOPB | VSSOP        | DGK             | 8    | 3500 | 367.0       | 367.0      | 35.0        |
| LMV824MTX        | TSSOP        | PW              | 14   | 2500 | 367.0       | 367.0      | 35.0        |
| LMV824MTX/NOPB   | TSSOP        | PW              | 14   | 2500 | 367.0       | 367.0      | 35.0        |
| LMV824MX/NOPB    | SOIC         | D               | 14   | 2500 | 356.0       | 356.0      | 35.0        |
| LMV824NDGVR      | TVSOP        | DGV             | 14   | 2000 | 356.0       | 356.0      | 35.0        |

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| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LMV824Q1MAX/NOPB | SOIC         | D               | 14   | 2500 | 367.0       | 367.0      | 35.0        |
| LMV824Q1MTX/NOPB | TSSOP        | PW              | 14   | 2500 | 367.0       | 367.0      | 35.0        |

**TUBE**


\*All dimensions are nominal

| Device          | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LMV822M         | D            | SOIC         | 8    | 95  | 495    | 8      | 4064   | 3.05   |
| LMV822M         | D            | SOIC         | 8    | 95  | 495    | 8      | 4064   | 3.05   |
| LMV822M/NOPB    | D            | SOIC         | 8    | 95  | 495    | 8      | 4064   | 3.05   |
| LMV824M/NOPB    | D            | SOIC         | 14   | 55  | 495    | 8      | 4064   | 3.05   |
| LMV824MT/NOPB   | PW           | TSSOP        | 14   | 94  | 530    | 10.2   | 3600   | 3.5    |
| LMV824MT/NOPB   | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |
| LMV824Q1MA/NOPB | D            | SOIC         | 14   | 55  | 495    | 8      | 4064   | 3.05   |
| LMV824Q1MT/NOPB | PW           | TSSOP        | 14   | 94  | 495    | 8      | 2514.6 | 4.06   |



# DCK0005A



# PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



4214834/E 06/2024

**NOTES:**

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

# EXAMPLE BOARD LAYOUT

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:18X



SOLDER MASK DETAILS

4214834/E 06/2024

NOTES: (continued)

- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE: 18X

4214834/E 06/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

# DGK0008A



# PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

**NOTES:**

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

DGK0008A

<sup>TM</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

# DBV0005A



# PACKAGE OUTLINE

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214839/J 02/2024

### NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

# EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214839/J 02/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

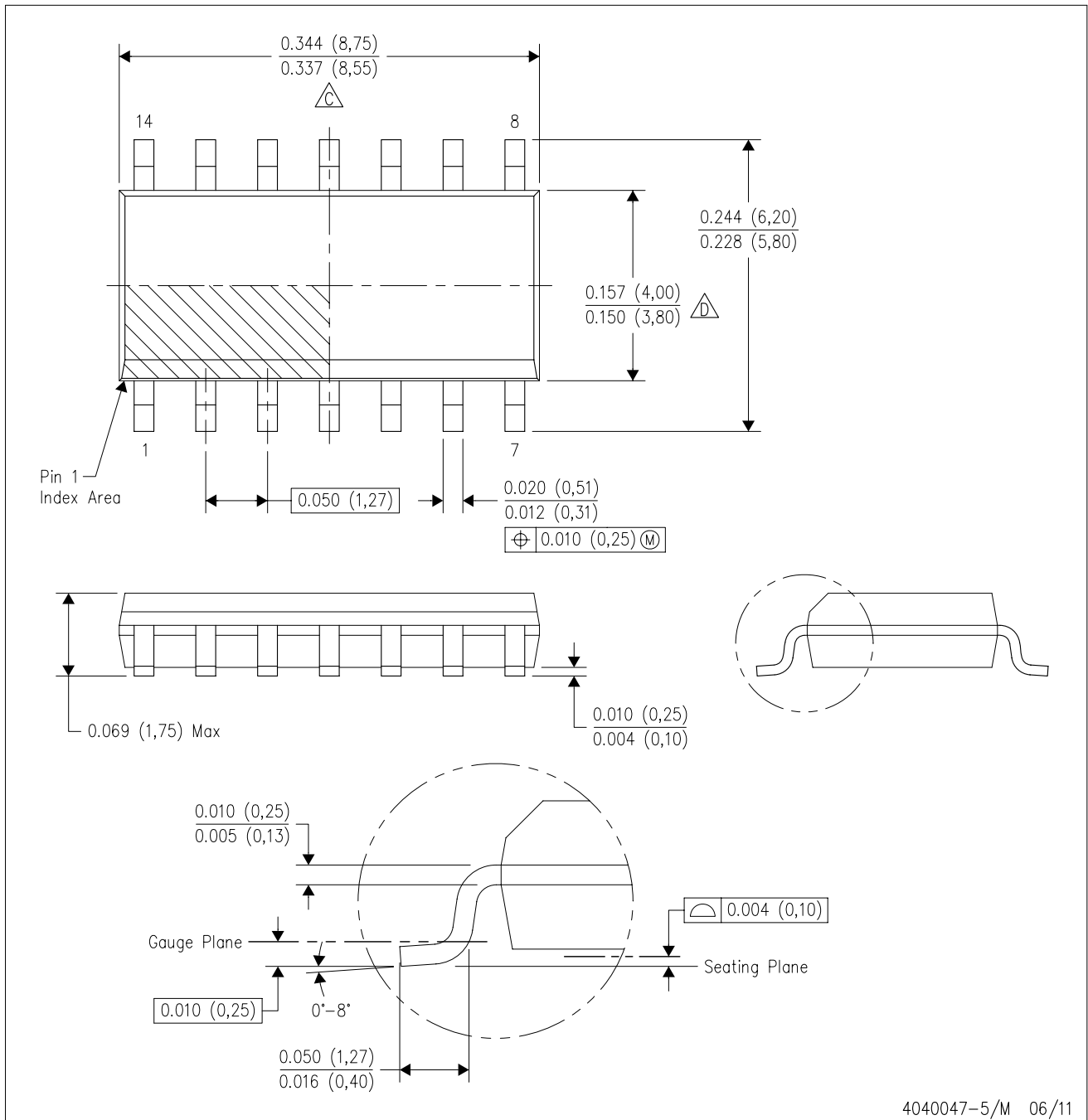
4214839/J 02/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040047-5/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  -  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  -  Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153



D0008A

# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

### NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed  $.006$  [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
 EXPOSED METAL SHOWN  
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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